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SENSITIVE ISOTROPIC ANTENNA WITH FIBER-OPTIC LINK TO A CONVENTIONAL RECEIVER

E.B. Larsen J.R. Andrews E.E. Baldwin

Electromagnetics Division Institute for Basic Standards National Bureau of Standards Boulder, Colorado 80302

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Prepared for U.S. Army Electronics Command AMSEL-NL-C Fort Monmouth, New Jersey



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SENSITIVE ISOTROPIC ANTENNA WITH FIBER-OPTIC LINK TO A CONVENTIONAL RECEIVER

ABSTRACT

A broadband, active, isotropic receiving antenna was developed at NBS for the frequency range 15 kHz to 150 MHz. It was designed for use with a conventional receiver to measure weak, near-zone electric fields of unknown polarization, such as leakage emanations from electronic equipment placed within a shielded enclosure. The antenna system consists of three mutuallyorthogonal active dipoles, each 31 cm long by 3.5 cm diameter. The entire frequency range of each of the three field components is amplified and used to modulate a high-speed light emitting diode (LED) located inside the dipole. The modulated infrared (IR) signals are guided through glass fibers 10 meters long which connect the "isolated" dipoles to avalanche photodiodes at the far end of the fiber guides. These photodetectors recover the rf modulation from the IR carrier for input to the receiver.

The fiber-optic antenna system described in this paper has high sensitivity (down to 10 μ V/m) and fast response time (rf modulations up to 150 MHz). The readout indication at each receiver frequency is proportional to the Hermitian magnitude of E, which is the root-sum-square value of three orthogonal E field components at the measurement point. The linear dynamic range of the antenna system depends on the receiver bandwidth and signal frequency. It is 70 to 75 dB at frequencies between 0.02 and 2 MHz (for 0.5 kHz receiver bandwidth), 60 to 70 dB between 2 and 25 MHz (for 5 kHz receiver bandwidth) and 40 to 55 dB between 25 and 200 MHz (for 50 kHz bandwidth).

Key words: Electromagnetic compatibility; fiber optics; field strength measurement; isolated EMC antenna; sensitive isotropic probe.

1. INTRODUCTION

1.1 Background to the Measurement Problem

Improved receiving antennas are required in order to make meaningful measurements of near-zone fields and permit rapid surveying without requiring time-consuming multiple orientations of the pickup antenna. The radio frequency (rf) sensor should be small and operate without metal transmission lines to minimize distortion of the field being measured. This would permit more accurate measurement of electromagnetic interference (EMI) radiated by nearby sources within a shielded enclosure, avoiding errors caused by large antennas located close to equipment racks or enclosure walls. As reported in the literature, errors of 40 to 50 dB can occur when measuring radiated emissions inside screen rooms [1 and 2].¹

¹Figures in brackets indicate the literature references at the end of this paper.

The errors in measuring fields inside shielded rooms are caused mainly by conductive surfaces which set up multipath reflections and standing-wave resonances in these high Q "cavities." Also, the impedance characteristics and effective length of the pickup antennas used are altered by close proximity to the equipment under test and to the metal enclosure. Limited success at solving this measurement problem has been reported for frequencies above 200 MHz by using absorbent walls and "hooded" antennas [3 and 4]. Measurements below 200 MHz may suffer large errors but improved techniques are being studied [5 and 6]. Figure 1 shows a typical setup for measuring radiated emissions inside a shielded room.

Two recent developments now permit more accurate measurements of electric field strength in the near zone of antennas or the leakage field of unknown sources. The first development is an "isolated" antenna system, that is, one having electric isolation (no metallic conductors) between the antenna and receiver. The other development also features electrical isolation but combines it with an rf sensor having isotropic response [7]. The latter property is desirable for making measurements in shielded enclosures because the pickup is independent of field orientation. Thus it is not necessary to determine experimentally the antenna orientation of maximum response, or map an elliptically polarized field, or make separate measurements of three orthogonal electric field components.

Two different techniques are presently employed to fabricate an isolated rf probe. One uses a high resistance transmission line such as carbonimpregnated plastic to convey the detected antenna pickup to a high impedance, direct current (dc) readout meter [8]. This type of probe is generally used to map high level fields and search for possible rf hazards in the range of 1 to 1000 V/m. In this case the total rf pickup, at all frequencies, is detected at the center of the dipole and no attempt is made to measure the amplitude as a function of frequency.

A second and newer technique for achieving electrical isolation between an (active) antenna and receiver makes use of a fiber-optic transmission link [9]. An earlier fiber-optic system [10 and 11] uses an "optical transmitter" consisting of a single 48 cm dipole, rf amplifier, and light emitting diode (LED). The glass fiber "waveguide" is coupled to an "optical receiver," using a semiconductor photodiode or photomultiplier tube to detect the modulated infrared signal. A similar approach is used for the probe developed at the National Bureau of Standards (NBS). However, the NBS antenna uses three orthogonal dipoles to achieve an isotropic response. Also, the electronic package of each active dipole (rf amplifier, LED, battery, etc.) is contained entirely within the dipole.

Isotropic probes have been employed in the past, but only for measuring intense fields. The rf sensors consist of 3 mutually-orthogonal dipoles and their associated detectors. The sensitive antenna described in this paper represents a different design philosophy in which both the amplitude and frequency information are preserved, and phase information could be recovered if desired. This contrasts with the usual type of "hazard" probe in which only the amplitude (energy density) is measured.

1.2 Objectives of the ECOM/NBS Contract

The overall objective of this project sponsored by the U.S. Army Electronics Command (ECOM) is to develop a broadband, isotropic receiving antenna with high sensitivity for measuring weak rf emanations from electronic equipment in a screen-room environment. The frequency range of interest is 15 kHz to 200 MHz. In order to avoid the large ambient fields of radio and TV stations at a field site, it is often necessary to make these tests inside a shielded enclosure. The antenna should thus permit measurement of the absolute magnitude of weak "leakage" fields having arbitrary polarization. Also, it is desired that the antenna system be compatible for use with a conventional field intensity meter (FIM) so as to measure level vs. frequency.

The limits for REO2 narrowband electric-field (E) emissions are specified in MIL-STD-461 [12 and 13]. The desired measurement sensitivity for the receiver system is given by figure 21 of MIL-STD-461A or figure 10 of MIL-STD-416B, reproduced here as figure 2. As shown, the specified limit of radiated field strength varies with frequency, being most stringent at 25 MHz where it is 10 μ V/m or 20 dB above 1 μ V/m (20 dB μ V/m). The limit at 15 kHz (low frequency end of spectrum) is 35 dB μ V/m and at 200 MHz (high frequency end) is 34 dB μ V/m. Thus, one important objective is to design an isolated antenna with sufficient sensitivity to measure these low field levels.

A typical test setup for measuring radiated emission according to MIL-STD-461 uses a vertical monopole antenna above a small horizontal ground plane. The vertical whip is placed one meter from the equipment under test (EUT). This specified distance is in the near zone of the EUT source (< 1 λ) for frequencies below 200 MHz. The resulting wave impedance is thus not necessarily 377 Ω , the field polarization is not necessarily vertical, and the perturbing effects of the antenna or coax cables are unknown. The pickup antenna developed at NBS is an attempt to reduce these problems. It uses three mutually-orthogonal balanced dipoles as an isotropic field sensor. Each dipole has a length of 31 cm and a diameter of 3.5 cm.

1.3 Characteristics of an Ideal rf Probe

Some characteristics of an <u>ideal</u> antenna for surveying near-zone electric fields can be listed as follows:

- Isotropic sensor -- The E field response should be independent of angular orientation and field polarization.
- (2) Isolated sensor -- The antenna should not require a conducting transmission line. If a transmission line is used, it should be "invisible" to avoid perturbation of the rf field being measured. (The NBS probe uses a glass fiber line to convey information between the antenna and receiver.)
- (3) Broad bandwidth -- The sensor should cover a large frequency range with no required tuning.
- (4) Flat response -- The antenna factor should be independent of the signal frequency to be monitored.
- (5) Small sensor -- The probe sensor should be small in order to minimize scattering. If dipoles are used, they should be electrically short rather than resonant, thus not requiring adjustment of length. (A 31 cm dipole is "short" up to about 200 MHz.)
- (6) High sensitivity -- The antenna response should be adequate to measure the very weak radiated fields specified in MIL-STD-461, that is, field strength as low as 10 μ V/m.
- (7) Low noise response -- The internal noise of the active antenna should be low because the ultimate sensitivity is controlled by signal-to-noise ratio rather than by the amplifier gain.
- (8) Large dynamic range -- The active antenna should have a wide range between the weakest measurable field and the strongest field with acceptable overloading.
- (9) Fast response time -- The overall response time of the receiver system should be short, permitting rapid spatial probing and rapid frequency scanning. (The NBS-designed system is quite slow due to the long response time of the EMI receiver used.)
- (10) Good stability -- The measurement system should be stable with respect to both time and environmental conditions.

In addition to the characteristics listed above, it is desirable that the sensor measure a scalar rather than a vector quantity. This is inherent in the concept of an isotropic probe. The meter indication of the measurement system designed at NBS is a quantity known as the Hermitian magnitude of the electric field, defined in section 2.

2. TECHNICAL APPROACH

The approach used for the sensitive isotropic probe is shown in the block diagram of figure 3. The frequency range is 15 kHz to about 200 MHz. Each separate dipole of the isotropic antenna is electrically short (rather than self resonant) in order to achieve a large bandwidth. A field effect transistor (FET) is used for the input stage in each highly-reactive dipole. All signal frequencies induced in each dipole are amplified by a broadband amplifier and applied to a forward-biased LED. The resulting rf-modulated infrared emissions from the three LED's are transmitted via glass fiber lines to photodetectors in an electronic instrumentation package located near the antenna-input terminal of a conventional EMI receiver. The small antenna package and fiber-optic guides do not significantly perturb the field being measured.

The equivalent circuit of each pickup dipole is essentially a voltage source in series with a capacitance. The induced open-circuit voltage (V_{oc}) is approximately equal to the product of the field strength E and the halfdipole length. In other words, at frequencies up to 200 MHz:

$$V_{oc} = E L_{eff} \approx E \frac{L_a}{2}$$
(1)

where: L_{eff} = Effective length of each dipole L_a = Physical length of each dipole.

The actual input level (V_{in}) to the FET rf amplifier is reduced by a capacitive voltage-divider effect, as given by the equation:

$$v_{in} \approx v_{oc} \left(\frac{C_a}{C_a + C_g + C_i} \right) = v_{oc} \left(\frac{C_a}{C_a + C_s} \right)$$
(2)

where: $C_a = Effective$ antenna source capacitance $\approx 3 \text{ pF}$

 C_{g} = Stray capacitance at the center gap of the dipole \approx 1 pF

 C_1 = Input capacitance of the FET stage \approx 2 pF

 $C_{s} = Total shunt capacitance = C_{a} + C_{i} \approx 3 pF.$

The isotropic field sensor consists of three mutually-orthogonal dipoles, each 31 cm long, with approximately a common center. Because the induced signal currents are at right angles to each other, the dipoles respond independently to the impressed field. That is, the current on one dipole does not induce an unbalanced potential across the gaps of the other two dipoles. The induced voltages developed across the center gaps of the individual dipoles are given by:

$$V_x = E_x L_{eff}, V_y = E_y L_{eff}$$
 and $V_z = E_z L_{eff}$ (3)

where E_x , E_y , and E_z are the amplitudes of the E-field components along the three orthogonal dipoles. An effective field strength magnitude |E| can be defined as the root-sum-of-squares (RSS) value of electric field according to the equation

$$|E| = \sqrt{E_x^2 + E_y^2 + E_z^2}.$$
 (4)

The scalar quantity |E| is known as the Hermitian magnitude of the electric field. It is proportional to the square root of the electric-field energy density at the measurement point. Each dipole of the isotropic probe must be calibrated in a known "standard" field. The induced voltages from the three dipoles are processed electronically according to eq. (4).

Since a good E-field sensor must be able to measure close to a source or scattering surface without perturbing the field, it is necessary that the scattering from the probe be small. This criterion is satisfied by an antenna made of electrically-short dipoles. It has been shown experimentally [14] and theoretically [15] that the scattering cross section of a dipole decreases rapidly as the length decreases below 1/2 wavelength. A 31 cm dipole, which is self resonant at about 500 MHz, can therefore be used at all frequencies of interest in this project.

A sketch of each untuned, broadband, receiving dipole is shown as follows:

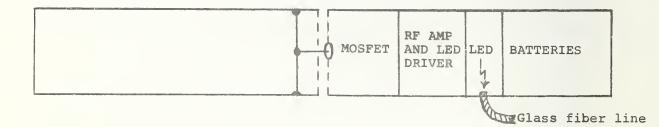


Figure 3 on page 43 is a block diagram of the isotropic-antenna receiving system. The received signal for each of the three channels is timemultiplexed by an rf switch at the antenna input of the conventional EMI receiver. The dc outputs from the receiver (synchronized with the rf input switch) are processed to give a dc voltage proportional to the Hermitian magnitude of the field. This voltage is used to drive a field-strength readout meter which is separate from the regular meter of the EMI receiver.

The sensitivity requirements for measuring field strength specified in MIL-STD-461/462 are shown in figure 2. These field limits, plus the resulting requirements for measuring antenna voltage, are listed in table 1 for several frequencies.

3. OPTICAL TRANSMISSION LINKS

3.1 Discussion of Infrared Fiber Optics

The type of electrically-isolated isotropic antenna described in this report depends for its success on using a fiber-optic link between the pickup antenna and receiver. This approach is relatively new for EMI antennas. A discussion of infrared fiber optics is therefore included early in this report.

3.1.1 System Considerations [16 to 22]

The building blocks for one type of active antenna system with fiberoptic link are shown in figure 3. The basic components are: pickup antenna, rf amplifier, optical source and means to modulate this source with the rf signal, fiber transmission line, and a photodetector at the receiver to recover the rf modulation. Table 2 lists some of the advantages of using an optical link between the antenna and receiver. At the present state-of-theart there are some disadvantages to fiber-optic communications, and these are also listed in table 2. However, opto-electronic systems are receiving considerable attention for various uses and a few of these proposed applications are listed in table 2, including isolated links to EMI antennas.

It could be mentioned that as the "carrier" frequency increases, the usable modulation band also increases. An infrared (IR) carrier is thus theoretically capable of transmitting a huge signal bandwidth. Also, when using fiber-optic lines, the transmission loss is independent of the rf modulation frequency. This is because the modulation frequency is such a small percentage of the carrier (IR) frequency. By contrast, the attenuation in coaxial cable increases rapidly as the frequency increases. For example, the attenuation of rf signals in a 10 meter length of RG-8A/U coaxial cable is about 0.05 dB at 1 MHz and 2.5 dB at 1 GHz.

3.1.2 Infrared Sources [23]

A good IR source for use in an isolated antenna system is a semiconductor light emitting diode. An LED emits radiation through the mechanism of electron-hole recombination in the PN junction region. Figure 4 shows typical emission spectra of IR LED and laser sources, comparing them with the response curves of silicon photodetectors and the human eye. Note that 1 micron = 1 micrometer = 1000 nanometers = 10,000 angstrom units.

Gaseous lasers are also being used for optical communications, but they generally have high cost, large size, short life, and large voltage and power requirements. In addition, they cannot be modulated easily or directly. Therefore, an LED is considered the optimum source for a fiber-optic system, especially if it must be battery operated and contained inside a small rf probe. Gallium Arsenide (GaAs) is the oldest and most highly developed semiconductor material used for LED's.

At the beginning of the NBS ECOM contract in mid 1974, two types of solid-state <u>laser</u> diodes had been described in the literature, but were not available commercially. One type (neodymium-doped yttrium aluminum garnet) required an intricate external modulator, which precluded its use in an isolated antenna. The other type (single heterostructure gallium arsenide) could not operate continuously at room temperatures. In the past, semiconductor laser diodes were not able to produce coherent continuous-wave (CW) radiation except at liquid nitrogen temperatures. At room temperature they were limited to pulse-type operation because of internal heating. Very recently, however, CW injection laser diodes for room temperature operation have been announced (double heterostructure gallium aluminum arsenide). Some of these have been received for testing at NBS. However, they were not available in time for use in this project. Also, the battery current requirement for laser operation is high, and the lifetime is unpredictable and relatively short.

Above the lasing threshold of a GaAs diode, there is a steep rise in the IR output and thus much higher efficiency. In the remainder of this report a diode operated above this threshold will be referred to as a "laser diode," and a sub-laser diode will simply be called an LED. The term efficiency as applied to an optoelectronic emitter is defined as follows:

Power conversion efficiency =
$$\frac{\text{Optical power output}}{\text{Electrical power input}}$$
. (5)

An ordinary LED has low efficiency according to the above definition, typically about 1%. Also, as indicated in figure 4, the spectral line of an LED is relatively broad, typically about 35 nm for an LED and about 2 nm for a laser diode. This causes velocity spread in a long transmission line and thus limits the maximum usable modulation frequency. In addition, an LED radiates into a larger solid angle than a laser diode. The radiation angle is typically about 30°, making it difficult to focus or couple the IR radiation into a propagating mode of the glass filament. The coupling loss into a fiber is about 15 dB greater for an LED than for a laser diode. Also, laser diodes are inherently much faster than LED's, permitting higher modulation frequencies. The maximum theoretical overall efficiency of an (LED/glass fiber/photodiode) system is about 0.0001, or a reduction in carrier power of about 40 dB.

One major <u>advantage</u> of the LED source is that it can be modulated directly and easily by varying the forward current through the diode. No external modulator is required; the rf signal is simply superimposed on the dc "bias" current. As indicated in figure 5, the intensity of the IR radiation is proportional to the LED drive current. When the rf signal is larger than the dc bias, severe clipping results. An increase in drive current then produces only a small increase in radiation intensity. This point of non-linearity is the upper limit of the dynamic range for the transmission system.

Table 4 gives the characteristics of a few commercially-available highspeed LED's. These values are the CW specifications according to the manufacturers' literature.

3.1.3 Fiber Transmission Lines [24, 25 and 26]

The transmission of light inside a fiber is by a process of multiple internal reflections. The maximum angle for total internal reflection is given by Snell's law of refraction. The numerical aperture (NA) of a fiber guide is a measure of the acceptance cone of radiation into the end of the guide from an external source. The larger it is, the greater is the fraction of light trapped inside the fiber guide. (NA) is defined as the sine of the critical angle θ_c , the maximum acceptance angle between the ray and the fiber axis. It is given by:

(NA) =
$$\sin \theta_{c} = \sqrt{(n_{2})^{2} - (n_{1})^{2}}$$
 (6)

where: $n_2 = Index$ of refraction of the core material $n_1 = Index$ of refraction of the cladding.

Similar to rf waveguides, an optical fiber can propagate either in a single mode (if the diameter is small enough) or in many modes. A typical single-mode fiber for IR wavelengths has a core diameter of about 2 μ m. As indicated in [17-26], this type of fiber has the lowest loss. However, the small core size makes it difficult to couple energy into the fiber and only coherent laser sources are coupled efficiently.

Multimode fibers have a core diameter of about 100 μ m. This permits easier coupling to less expensive sources such as LED's. However, the number of propagating modes increases as the (NA) and fiber diameter increase. The different modes propagate with different velocities, causing dispersion of the signal and a lower possible modulation frequency. In spite of this limitation, large multimode fibers appear to be the optimum guide for use with an LED source, especially for short transmission lines such as those used between an antenna and EMI receiver. The typical coupling loss between an LED and a fiber bundle is 20 to 25 dB.

3.1.4 Infrared Photodetectors

Demodulation of an IR signal carried in a fiber waveguide can be accomplished with either a photomultiplier tube (PMT) or a semiconductor photodetector. Both types were evaluated in this project. The detector chosen is a silicon avalanche photodiode (APD). This type of semiconductor photodiode is operated with a high reverse bias voltage. As the bias approaches the breakdown voltage, hole-electron pairs created by the absorbed IR photons generate additional pairs by avalanche multiplication. This process is similar to electron multiplication in a photomultiplier tube; that is, an APD is the solid-state equivalent of a PMT. The avalanche effect produces a multiplication factor (current gain) up to about 100. For linear operation the output <u>current</u> must be proportional to the input IR power.

The APD multiplication process also creates additional noise, mainly shot noise. There is an optimum reverse bias voltage (or APD current) which results in sufficient gain and highest signal-to-noise ratio. This optimum value must be determined experimentally for each length and type of fiber guide, and for each set of operating conditions. Table 5 gives the characteristics of a few commercially available photodetectors, according to the manufacturers' specifications.

3.2 Tests of Fiber-Optic Components

Initial experimental work dealt with evaluation of the opto-electronic components required in the infrared link between the antenna package and EMI receiver. One commercially available LED appeared to be the most promising on the basis of a published risetime of 1 ns, which is equivalent to a 350 MHz bandwidth. However, the fastest measured risetime was 12 ns (\sim 30 MHz) for this LED. The test setup consisted of a 1 ns risetime pulse generator, a 150 ps avalanche photodiode, a 420 ps rf amplifier, and a 700 ps oscilloscope. The measurement system risetime was 1.3 ns. The relationship between the 10-90% risetime (T_r) and the -3 dB bandwidth (BW) is given by the expression:

$$(T_r)(BW) \approx 0.35.$$
 (7)

The optical output of an LED is quite weak, typically about 500 µW at a bias current of 50 mA. Considerable rf amplification is required after the photodiode to observe the rf signal on an oscilloscope. The efficiency of an LED is quite low, typically 1% (mW optical output/mW electrical input). Also, the output beam from an LED is broad, at least when compared to a laser. The -3 dB beamwidth is typically 30°. A lens system was used in our early tests to focus the LED output onto the photodiode.

Photodetectors from several manufacturers were evaluated for transient response using a mode-locked dye laser (30 ps risetime) or a pulsed GaAs laser diode (150 ps risetime). Several PIN photodiodes and avalanche photodiodes were tested. Both types produced good linearity for analog applications, but (in our system) the PIN diodes did not produce as good an overall noise figure as the APD's.

Also, a photomultiplier tube was compared with the solid-state avalanche photodiode. It had been reported in the literature that a PMT is capable of higher speed and sensitivity than an APD. For this reason a series of tests was made using a phototube which has maximum sensitivity near the desired wavelength of 0.9 nm. We determined an optimum value of PMT anode current, which is a function of the PMT anode voltage and luminous flux. A current of 10 µA, produced by an anode voltage of 700 V, gave the highest signal-tonoise ratio in our system. The PMT was able to sense a weaker infrared beam than the APD, but the speed and rf signal sensitivity were greater (in our system and for our application) when using an APD. The experimental data are given in section 5.4.

Silicon avalanche detectors are commercially available with gainbandwidth products up to 100 GHz. For an avalanche gain of 100, the attainable signal bandwidth is thus 1 GHz. It can be seen that photodiodes are not the limiting factor in achieving large bandwidth in a fiber-optic system. The upper usable frequency in our system appeared to be limited by the carrier lifetime of the LED. Heterodyne conversions employing an rf local oscillator inside the active dipole could perhaps be used to achieve higher effective signal frequencies; however, an experimental investigation of this approach was not pursued.

Measurements were made of the frequency response of 17 LED's and 1 laser diode operated as an incoherent LED. These were all different types from various manufacturers. A pulsed laser was used to evaluate the response time of 8 regular photodiodes, 6 PIN photodiodes and 4 avalanche photodiodes. The emitter/detector pair chosen for the NBS fiber-optic system is a spectrally matched LED/APD pair optimized by the manufacturer for a wavelength of 800 to 900 nm.

The type of fiber bundle chosen consists of 19 glass filaments packaged in a plastic jacket with a connector at each end, similar in appearance to a coaxial cable. The outer diameter of each coated filament is 135 μ m, with a core diameter of 85 μ m. The numerical aperture of the guide is approximately 0.14, which means that the maximum acceptance angle is ± 8° to the fiber axis.

One problem in fiber-optics is the high attenuation of the optoelectronic portion of the system. Also, the risetime of all LED's tested was > 10 ns, which limits the -3 dB bandwidth to 35 MHz. Thus, considerable frequency compensation was required in the rf amplifier in order to achieve a system response up to 200 MHz. Considerable difficulty was also experienced in capturing the limited power radiated by the LED's. Using typical published values for GaAs LED's and silicon photodiodes, the theoretical minimum coupling loss between an LED and an APD is 40 dB. For example, assume an LED efficiency of 1 mW/50 mA current and a photodiode responsivity of 0.5 mA/mW. The maximum current transfer ratio for the LED/APD pair is

I_{out}/I_{in} = LED efficiency x APD responsivity = 0.01, or -40 dB.

We were not able to achieve the above overall efficiency in practice. With both butt-joints between the LED and APD touching, or when using lenses on X-Y-Z micrometers to focus the LED output on the APD, we experienced typical losses of 70 to 75 dB. An optical power meter was assembled and calibrated at NBS in order to measure the power output coefficients during this development work.

Time-domain evaluations were made of several promising types of Si avalanche photodiodes. The first type of APD tested produced a small-signal avalanche gain of 16 dB with 330 volts of reverse bias. Its measured 10-90% risetime was 2.5 ns, compared with a specified risetime of 2 ns. This corresponds to a -3 dB bandwidth of 140 MHz. It was found that infrared APD's are sensitive to stray radiation and must be kept shielded from ambient light during measurements on an optical bench.

The second type of APD evaluated was tested for photocurrent gain and internal random noise as a function of bias voltage and temperature, from +10°C to +50°C. Figure 6 is a plot of the measured results at an ambient temperature of 28°C. The gain and noise are both strongly dependent on temperature. With a regulated-voltage APD bias of 160 volts, the photocurrent gain (also called avalanche multiplication) ranged from 42 dB at +10°C to 30 dB at +50°C. The optimum operating point for this particular APD (at room temperature) was at 160 volts. As shown in figure 6, the output signal-to-noise ratio (S/N) for this condition is about 45 dB.

3.3 Measurements of Two Infrared Optoelectronic Links

3.3.1 Performance of a Radiated System

An experimental infrared broadband transmission link was assembled and tested. Figure 7 is a block diagram of the system. The arrangement is similar to that of the final system, except that this first test did not use a fiber guide. The modulator for the LED is a low-current drain (10 mA) rf amplifier. The bandwidth of this first design was 60 MHz. The IR output from the LED was focused by lenses onto the photodiode. The detected signal was amplified by two wideband amplifiers and applied to the input terminal of a spectrum analyzer used as a sensitive rf voltmeter.

Figure 8 shows the input/output performance characteristics of the IR link for a signal frequency of 25 MHz. With a 100 Hz bandwidth the spectrum analyzer noise level was -110 dBm (0.7 μ V) for a 10 dB(S+N)/N ratio. The upper limit for linear operation was about -35 dBm input. The overall attenuation of the rf signal in the IR link was 7 dB in this test. As seen in figure 8, the dynamic range achieved in this first test was 65 dB, which was greater than anticipated. It should be noted, however, that a typical EMI receiver has a larger bandwidth than the 100 Hz used in this test. A bandwidth would reduce both the sensitivity and the dynamic range.

3.3.2 Performance of a Fiber-Optic System

The optimum wavelength to use for a fiber-optic system must be chosen on the basis of three considerations: (a) high source radiation, (b) low fiber absorption, and (c) high photodetector efficiency. The near IR portion of the electromagnetic spectrum (800 to 900 nm) is a good choice for transmission in glass fibers. GaAs LED's have a peak output near 900 nm so this wavelength was chosen for our system.

The fiber waveguide chosen consists of a bundle of 19 filaments. The specified maximum attenuation in the guide is 0.03 dB/m, at a wavelength of 820 nm. However, this low value of attenuation was not achieved in practice. Initial measurement of the bundle attenuation was 3.3 dB for a guide 10 m long, using a focused He-Ne laser beam. However, when using an LED the measured system loss was 28 dB, for either an (LED/fiber) butt joint or with a set of focusing lenses. These measurements were made using an optical power meter. It should be emphasized that the major loss was not the attenuation within the fibers but was due to the difficulty of injecting the LED radiation into the fiber.

When passing an rf signal through an (LED/fiber/APD) link, the <u>additional</u> loss due to the waveguide was typically 45 to 50 dB. The apparent discrepancy between the rf attenuation and the optical power measurements (28 dB above) is caused by the linear optical-power to electrical-current conversion by the APD. If the modulation current (rf signal) is passed through a load resistor, the power delivered to the load is proportional to the current squared. Thus a given dB infrared power loss causes an output rf signal power loss of double that number of dB.

The instrumentation used to measure the rf signal loss in a fiber-optic system is given in figure 9. The LED driver circuit was an emitter follower in series with a matching network. As shown in the simplified schematic, the matching network was a 40 Ω resistor in parallel with a variable capacitor, which was tuned for maximum output. The maximum usable modulation frequency for an LED depends partially on the driver circuit's ability to supply charging current to the LED's capacitance. The input capacitance of high-frequency LED's is typically 100 to 1000 pF. Also, this capacitance is shunted by a low dynamic resistance of only a few ohms. One method to drive such a source would be by brute force, using a high-current, low-impedance rf source. Another approach, a constant-current LED driver, was used in our system because it avoids the large dI/dt requirement for high frequency modulation.

Figure 10 gives the measured values of overall rf signal attenuation as a function of frequency. The minimum insertion loss, at low frequencies, was about 60 dB for the APD temperature and voltage used. As seen, the insertion loss increased rapidly for signal frequencies above 100 MHz. Accurate measurements above this frequency could not be made (in this system) because of signal leakage between the rf source and receiver.

4. FIELD STRENGTH AND ANTENNA CALIBRATIONS

4.1 Discussion of Field Strength Meters

A receiver used as a frequency-selective voltmeter is the keystone of any system for measuring field strength and interference. Figure 11 is a block diagram of a typical FIM. It consists basically of a superheterodyne communications receiver with certain added features. The model EMC-25 receiver² used for this project is a solid-state "interference analyzer" covering 14 kHz to 1 GHz in 15 tuning bands. There are three intermediate frequencies, depending on the tuning band in use. A multistage detection system with logarithmic response is incorporated in the IF amplifier section. This is done to achieve a readout scale which is linearly proportional to dB above 1 μ V. The detector function used for sine-wave signals

²The overall fiber-optic antenna system described in this report was designed to be compatible with an EMC-25 type of field intensity meter. This type of receiver was chosen because it is a typical FIM and because it was available both at NBS and at the sponsoring agency. The use and identification of the receiver type number does not imply recommendation or endorsement by the National Bureau of Standards, nor does it imply that the equipment identified is necessarily the best available for the purpose. Identification of the FIM type will, however, enable another experimenter to reproduce the equipment and results described in this report.

has a nominal time constant of 600 ms for both charge and discharge. A summary of the characteristics of the receiver for signal frequencies up to 200 MHz is given in table 6. The term "tangential sensitivity" used here is defined as the input signal level required to increase the meter reading by 3 dB above the receiver internal noise. Table 7 gives data on the measured values of receiver bandwidth.

As mentioned previously, a short dipole antenna acts as a voltage generator of high (capacitive) impedance having a pickup which is essentially independent of signal frequency. By contrast, the induced voltage of a self-resonant dipole is inversely proportional to frequency. In order to measure absolute field strength with a receiver (rf voltmeter), it is necessary to apply a multiplying factor to the dial indication. This conversion factor between the antenna pickup (volts) and the electric field strength (volts/meter) is known as the "antenna factor." Figure 12 shows the theoretically-anticipated value of antenna factor vs. frequency for a passive $\lambda/2$ dipole. The factor for an active dipole must be determined experimentally by immersing it in a known (standard) field [27 and 28].

4.2 <u>Auxiliary Calibration of the Receiver as a</u> <u>Tunable rf Voltmeter</u>

The first phase in calibrating a receiver to measure field strength is to adjust the gain control setting, at the frequency of interest, in terms of a known sine-wave voltage. This is commonly referred to as "calibration" of the FIM as a tunable or frequency-selective rf voltmeter. Figure 13 is a block diagram of the instrumentation used for this project. The technique shown employs a special L-pad with 50 ohms input resistance and a very low output resistance. This attenuator pad has 57 dB insertion loss and consists of a selected 49.95 Ω series resistor and a 0.071 Ω annular-ring resistor in shunt with the output terminal. It is housed in a coaxial chamber 1 inch long, with 50 Ω characteristic impedance, and has a type N connector at each end. For each voltage calibration the output level of the signal generator is adjusted to obtain a power meter reading (accuracy of ± 1%) of 100 μ W. This produces a 100 μ V signal at the receiver input.

The 0.071 Ω resistor in figure 13 supplies a known <u>voltage</u> to the receiver which is essentially independent of variations in receiver input impedance. For example, assume the use of a receiver with nominal 50 Ω input but having an actual input VSWR of 2:1. The maximum possible variation of receiver input voltage under these conditions would be 0.017 dB or 0.2%. By comparison, the receiver input voltage could be in error by as much as 3.52 dB, or 50%, if a 50 Ω generator is used directly as the receiver "voltage" source.

Figure 14 is a graph showing the measured non-linearity of the particular receiver we used. It can be seen that the dial indication has a variation from true voltage level which exceeds 2 dB at some points. These corrections to the indicated values must be made manually in order to obtain more accurate measurements of CW voltage and field strength.

4.3 Standard Field Setup Used to Calibrate the Active Antenna

Initial tests of the 31 cm active dipole were made at a frequency of 25 MHz. Figure 15 shows the instrumentation used to establish a known electric field for calibrating the active dipole. The antenna factor and system sensitivity for the antenna under test were determined by immersing the dipole in the standard field of a transverse electromagnetic (TEM) cell [29]. This cell consists of a large "coaxial" 50 Ω transmission line in which the center conductor is a flat metal strip and the outer (grounded) conductor has a rectangular cross section. The TEM line we used (see figure 16) is about 3 m long and has a square 1.2 m x 1.2 m cross section. At frequencies sufficiently low so that only the principal wave (TEM mode) will propagate through the cell, a fairly uniform and calculable E field can be established. The electric field at these frequencies, at the location shown in figure 15, is given by:

$$E = \frac{\text{Voltage}}{\text{Distance}} = \frac{\sqrt{50 P}}{D}$$
(8)

where: E = Field strength, volts/meter

- 50 = Characteristic impedance of the cell
- 50 = Resistance of the cell termination, ohms
- P = Measured power through the cell, watts
- D = Distance between the center conductor and top of the cell, meters.

The 1.2 m x 1.2 m TEM cell exhibited cavity-mode resonances at frequencies above 140 MHz. This is similar to the well-known resonances occurring in shielded rooms. In order to calibrate the active dipole at frequencies above 140 MHz it was necessary to measure the field strength inside the cell with a small (10 cm) transfer probe, which in turn had been calibrated previously in a smaller TEM cell. The signal frequency vs. cell power required to produce a field level of 0.1 V/m was measured for a larger test probe having the same dimensions as the 31 cm active dipole. Corrections were thus made for field perturbations caused by the larger probe. The high Q of the TEM cell for higher order modes was reduced by placing several pieces of rf absorber in the bottom half of the cell. All subsequent tests of the active dipole sensitivity were made in this improved test chamber. It is felt that standard fields for calibrating the 31 cm active dipole were produced with an uncertainty less than ± 1 dB at any frequency up to 100 MHz and ± 2 dB from 100 to 200 MHz.

5. DESIGN OF A SINGLE-DIPOLE FIBER-OPTIC ACTIVE ANTENNA

5.1 Description of the Dipole Unit and APD Circuit

Physically each dipole antenna consists of two identical brass tubes 15.25 cm (6 inches) long and 3.5 cm in diameter, with a 0.5 cm gap at the center of the dipole. The overall dipole length is thus 31 cm. The rf amplifier, LED, fiber waveguide connector and battery all fit within one of the brass tubes. The second tube serves as the opposing half of the dipole antenna. The amplifier construction features microstrip and ground plane techniques to achieve wideband response in the rf amplifier and LED driver circuitry.

The rf amplifier and FET-input stage, as originally designed, had one major problem. The unit was small enough, but the circuit required 15 volts at 60 mA, an excessive battery consumption. The antenna circuit was then redesigned and now requires 30 mA at 9 volts, supplied by a NiCd rechargeable battery. Figure 17 gives a schematic diagram of the final circuit. The rf amplifier features a diode-protected MOS FET front end, Q 1. The input impedance presented to the antenna is 10 megohms resistance shunted by 3 pF capacitance. The amplifier has a -3 dB bandwidth of 170 MHz and nominal gain of 60 dB.

Figure 18 shows an equivalent circuit of the active dipole antenna. It is similar to that discussed in section 2, but includes an effective noise generator at the amplifier input. At frequencies below 200 MHz the source impedance Z_a is given approximately by the reactance of a 3 pF capacitor. This capacitance value was determined experimentally by mounting half of the dipole unit as a monopole above an extended ground plane. The measured capacitance was 5.4 pF, corresponding to a dipole source capacitance of half this value, or 2.7 pF. The nominal 3 pF value was also verified approximately by several theoretical calculations of dipole input imepedance. The shunt capacitance C_s of about 3 pF was determined by adding capacitance at the antenna gap until the pickup voltage in an rf field was reduced by a factor of two.

The APD required specially designed auxiliary circuits and power supply. Figure 19 gives a simplified schematic diagram. The circuitry provides temperature compensation of the APD avalanche voltage, which helps stabilize the APD gain. As shown in the figure, the temperature reference diode is

thermally connected to the APD by physically mounting the two components on a common heat sink. The APD bias voltage (and hence its avalanche gain) are adjustable. A crowbar circuit is included in the power supply to protect the APD, since if too much light is applied to the APD and/or the bias voltage is too high, the APD current will exceed its maximum permissible value. The APD current is sensed across the 1 k Ω output resistor and applied to the 741 operational amplifier (op. amp.) connected as a voltage comparator. If the current exceeds a preset value, the crow-bar transistor Q 3 turns off the high voltage bias supply. The circuit automatically resets when the overload is removed.

5.2 Preliminary Tests of the Active Dipole System

Figure 20 gives a block diagram of the prototype antenna system including the active dipole circuitry, LED, fiber guide and APD. An oscilloscope was used to observe the step response and operation of the system. The test signal (CW or step) was applied across a 50 Ω termination at the dipole gap. Table 8 lists the system gain and signal-to-noise (S/N) ratio for several frequencies as measured with a spectrum analyzer.

The 31 cm active dipole antenna was then used to pick up rf fields in the laboratory. Figure 21 shows the spectrum from dc to 200 MHz as received by the active antenna system. The lower white band is the system noise. The antenna system has also been demonstrated to receive TV signals from broadcast stations, as shown by the photographs of a TV screen in figure 22.

5.3 Effects of Noise and Receiver Bandwidth on Sensitivity [30 and 31]

Adequate performance of the infrared (LED/fiber guide/APD) system requires a combination of high sensitivity, low noise, and large antenna bandwidth. One of the most important requirements of any active antenna system is that the S/N ratio should not be degraded excessively between the rf pickup and the FIM. The FET input stage, rf amplifier and the process of converting to IR and back to rf should all maintain a high S/N ratio. In other words, the sensitivity and reception characteristics depend on the noise figure of the overall system. The S/N ratio must also be considered as a major criterion when determining the FIM receiver bandwidth that can be used. This is due to the fact that the random noise power received by an FIM is proportional to the receiver bandwidth.

The measured value of sensitivity for any receiving system depends on the definition or criterion used. One common term for receiver sensitivity is "minimum discernible signal" level (MDS), generally defined as the signal required to produce a receiver indication 0.5 dB above the background noise.

In this contract we chose to use a more conservative and more precisely measurable criterion known as "tangential sensitivity." It is defined as the field intensity required to increase the receiver indication 3 dB above the background noise level, or (S+N)/N = 3 dB.

In general, noise is defined as any unwanted disturbance which is superimposed on the desired signal. In this report the term noise is used for voltages which vary randomly in amplitude and phase, and which are present over a wider frequency band than the resolution bandwidth of the receiver. Therefore, the response of a receiver (or spectrum analyzer) depends on the resolution bandwidth used. Doubling the measurement bandwidth doubles the noise power accepted, which increases the receiver voltage indication by a factor of $\sqrt{2}$.

The maximum attainable sensitivity of any receiving system for narrowband signals is controlled by the signal-to-noise ratio. Since the noise contribution of an (LED/fiber guide/APD) system is greater than that of the rf amplifier, our approach was to minimize the noise in the optoelectronics and use the lowest possible receiver bandwidth. The noise problem in a fiber-optic antenna system is severe compared with a conventional antenna and receiver. The pickup antenna is intentionally broadband, to avoid tuning or adjustment, and has a large mismatch to the rf amplifier. This produces both a large noise pickup and a low signal level. In addition, the optoelectronic link causes a large attenuation (requiring further rf amplification) and a major addition to the random noise. Since the overall sensitivity is ultimately limited by noise, no amount of receiver gain can improve the sensitivity.

One method to obtain additional receiver selectivity at signal frequencies above 25 MHz, and thus higher tangential sensitivity, would be to use the "Q-fiver" technique familiar to radio amateurs. This involves loose coupling of the IF output of the conventional receiver to the antenna input terminal of another receiver with low intermediate frequency and narrow bandwidth. This technique of using narrow bandwidth to achieve high receiver sensitivity causes tuning inconvenience and does not apply to the measurement of broadband signals. For example, the impulse response voltage of a receiver as measured with a peak detector is directly proportional to the receiver bandwidth. Thus high sensitivity for impulsive signals (and ease of tuning for CW signals) is achieved by using a wide receiver bandwidth. The EMC-25 receiver is furnished with two selectable bandwidths labeled on the front panel as "narrow" and "wide." The former may be used for measuring CW signals and the latter for measuring noise and interference.

5.4 Measurements of the System Sensitivity

5.4.1 Sensitivity of the Active Dipole

Table 9 gives a summary of the measured sensitivity for the (dipole/ receiver) system at 25 MHz. It can be seen that CW sensitivity is a function of receiver bandwidth, dipole gap width, level of APD current, and the criterion used to define the term "sensitivity." On the basis of tangential sensitivity, using the EMC-25 receiver on narrowband selectivity, the active dipole developed at NBS meets the desired MIL-STD-461 specifications at 25 MHz if the receiver is on Band 10. The measured tangential sensitivity for a 0.5 cm dipole gap was 9 μ V/m and the required sensitivity is 10 μ V/m. However, if the receiver is tuned to 25 MHz on Band 11 instead of Band 10, the tangential sensitivity is 23 μ V/m which fails to meet the specification by 7 dB.

It appears from the data of table 9 that 50 μ A is about the optimum value of APD current when using the 2 m fiber guide. Also, it can be seen by comparing the last of two conditions in table 9 that it is not necessary (or helpful) to use an extra rf amplifier between the APD and the FIM. As noted previously, the MDS level could not be measured as precisely as the other three criteria and was therefore not used. The last column of table 9 gives data on the measured threshold noise level of the receiver. It shows the increase in noise floor caused by the fiber-optic system.

All of the sensitivity measurements in the remainder of this report are for a dipole gap width of 0.5 cm. Also, the remainder of the data were taken with the receiver switched to the narrowband position.

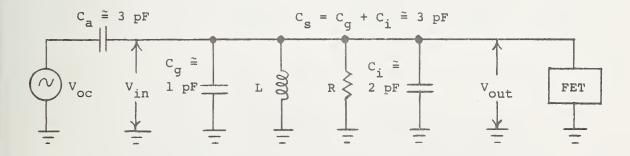
A series of measurements was made with the 31 cm active dipole to determine the system sensitivity as a function of signal frequency. Several criteria of sensitivity were used, varying from the MDS level to a signal 20 dB above the noise level. A summary of the data is shown in figure 23. For comparison purposes, similar measurements of system sensitivity were taken using a photomultiplier tube (PMT) instead of the APD. Figure 24 is a graph of the data (PMT vs. APD) for the case of tangential sensitivity.

The electronic circuitry of the rf amplifier in the antenna was optimized in an attempt to increase the sensitivity at frequencies above 25 MHz, while maintaining good performance at frequencies below 25 MHz. The circuit design includes frequency compensation to overcome some of the amplitude rolloff at frequencies above 100 MHz. This rolloff is caused mainly by frequency limitations of the LED. Figure 25 is a graph summarizing the measured sensitivity of the system after optimizing the rf amplifier. As can be seen, the sensitivity was improved significantly at frequencies between 25 and 150 MHz. The abrupt changes in sensitivity at signal frequencies of 2.3 MHz and 25 MHz are readily apparent; they are due to step changes in the receiver bandwidth. 20 In the remainder of this report the only criterion used for system sensitivity is "tangential sensitivity," the E field required to produce a receiver indication 3 dB above the noise. Using this criterion, the antenna system developed at NBS (with an EMC-25 receiver) meets the specifications of MIL-STD-461 for all frequencies from 20 kHz up to 25 MHz. As seen in figure 25, the sensitivity is slightly low at frequencies between 25 and 50 MHz and at frequencies above 100 MHz.

The antenna data in the remainder of this report are for an improved type of fiber guide 10 meters long, whereas a 2 m guide of less expensive material was used for all of the previous data. The loss of optical energy in the longer guide changed the antenna factor and caused a slight deterioration in the system tangential sensitivity. The relative loss was greater at the lower signal frequencies. Before taking quantitative data, the connectors at both ends of the fiber guides were adjusted until maximum IR transmission was achieved. This condition of maximum transmission is easily determined experimentally because it corresponds with maximum indication of APD current on the panel meter.

5.4.2 Effect of Using an Antenna Resonating Inductor

Antenna resonance can be used to produce a significant improvement in the system sensitivity at frequencies near resonance. A broadly resonant dipole can be obtained by connecting a low-Q coil across the center gap of the dipole. Theory indicated that a parallel inductor would boost the sensitivity over a frequency band of about one octave. No inductor would be used at frequencies below 25 MHz, or whenever the added sensitivity is not required. The following sketch shows the equivalent circuit for an electricallyshort dipole with an inductor connected across the center gap.



Equations for calculating the insertion loss due to the parallel coil are given by:

Insertion loss, dB = 20 log
$$\left(\frac{V_{oc}}{V_{out}}\right)$$
 - 6 (9)

$$\frac{V_{oc}}{V_{out}} = \sqrt{\left[2 - \frac{X_c}{X_L}\right]^2 + \left(\frac{X_c}{R}\right)^2}$$
(10)

where: $C \equiv C_a = C_s \cong 3 \text{ pF}$ (see eq. 2)

a s

L = Inductor connected across the antenna gap

R = Resistor connected across the antenna gap.

Figure 26 is a plot of the calculated gain for a 7 μ H coil, for four values of coil Q. Figure 27 gives actual measurements of system sensitivity vs. frequency for the three inductors chosen. As can be seen, the 23 turn toroid produces sufficient improvement near 25 MHz so that MIL-STD-461 is essentially satisfied from 25 to 100 MHz. In like manner, the 6 turn coil produces the required sensitivity in the frequency range of 75 to 150 MHz. The 4 turn coil can be used for improved sensitivity between 100 and 200 MHz, but we were not able to achieve sufficient improvement at frequencies above 150 MHz. At these higher frequencies it might be advantageous to use a series inductor, but this approach was not explored. A description of the 3 types of coils used in the final design is given in table 10. The coils were wound on ferrite toroid cores having a diameter of 0.64 cm and a thickness of 0.19 cm.

5.4.3 Effect of Non-coherence in the Fiber Bundle

The type of waveguide generally used for fiber-optic communications consists of a bundle of several glass filaments. Multifilament bundles are used to achieve flexibility of the guide together with a large numerical aperture. In a "coherent" bundle the relative positions of the fibers are maintained the same at both ends of the guide. This type of bundle <u>must</u> be used for imaging through a guide but is not required simply for transmission of energy. All of the "low loss" guides we tested use incoherent bundles. However, an LED chip is much smaller in area than the end of a fiber guide, so only a few of the filament ends are illuminated. This causes random spreading of the light beam along the length of the guide, so that only a fraction of the incident beam is captured by the small APD chip at the far end of the line. The longer the guide, the greater is the incoherence of the filaments in the emergent beam. As a result, the total transmission loss was found to be greater than that expected on the basis of path-length attenuation alone.

5.5 Overall Antenna Performance vs. Frequency: Tangential Sensitivity, Linearity, Dynamic Range and Antenna Factor

The design of the active dipole and fiber-optic link was optimized on the basis of three considerations, namely: (1) high overall sensitivity, (2) large dynamic range so as to receive weak signals, but keep spurious responses caused by strong signals to an acceptable level, and (3) wide bandwidth of the antenna so only one (isotropic) antenna unit is required over the total frequency range of 15 kHz to 200 MHz.

In the NBS antenna system (active dipole/fiber-optic link/FIM receiver) the dynamic range is controlled by, and defined as, the difference between the weakest measurable signal and the signal level strong enough to drive the system into non-linear operation [32]. More precisely, the dynamic range was defined as the difference between the tangential sensitivity [(S+N/N = 3 dB] and the point of 3 dB compression in gain. The latter point is where the receiver response falls 3 dB below a linear extrapolation of the characteristic curve plotted to give receiver response vs. field intensity. The overall design goal was to achieve high sensitivity and good linearity over a wide range of field intensity.

Tables 11 and 12 give a summary of the measured performance characteristics of the fiber-optic antenna system. Figure 28 is a graph of the raw data at four different receiver frequencies. On this graph an ideal curve is a straight line with a slope of 45°. The bottom (left) end of each line is a measure of the antenna system sensitivity. In fact, the bottom point is a plot of the tangential sensitivity. The curve becomes non-linear at the upper end of the line and tends toward a horizontal slope. This is where the rf amplifier or LED becomes overloaded. The length of the straight line portion is a measure of the system dynamic range.

The "antenna factor" is defined as the difference between the E field level (dB $\mu V/m)$ and the receiver indication (dB $\mu V)$. The lateral position of the characteristic curve is thus a measure of the antenna factor. An unknown field strength may be measured with the calibrated active antenna by using the expression:

$$E = M + K \tag{11}$$

- where: E = field strength, dB above 1 $\mu V/m$ M = meter indication of the receiver, dB above 1 μ V, on narrowband
 - selectivity, after calibration as a tunable voltmeter k = antenna factor, dB.

Figure 29 is a graph of the tangential sensitivity vs. frequency for the fiber-optic antenna system, from 15 kHz to 200 MHz. The figure includes the measured sensitivity when a parallel resonating coil is plugged into the antenna across the dipole center gap. Figure 30 is a graph of the dynamic range as a function of frequency. It also shows the calibrated value of antenna factor to be used when measuring field intensity.

The dynamic range of the fiber-optic antenna system generally decreases as the frequency increases. The measured dynamic range is about 70 dB at low frequencies, between 25 kHz and 2 MHz. It is about 65 dB for frequencies between 2 and 25 MHz, and 45 to 55 dB at higher frequencies up to 200 MHz. The use of a parallel antenna coil increases the sensitivity but appears to have little effect on the dynamic range. The dynamic range is fairly constant as a function of frequency when compared with either the tangential sensitivity or the overload level.

5.6 Overloading of the Active Antenna System by a Strong Interfering Signal

The (active-antenna/fiber-optic) system has a limitation regarding the measurement of absolute field strength. The antenna becomes desensitized by any strong signal within its total frequency range of 15 kHz to 200 MHz. A strong out-of-band signal may thus cause an error in the measured field strength at another frequency, or it may produce cross modulation products at various frequencies. This is a common limitation when using active antennas. In this case the same signal may be picked up at more than one receiver frequency. For example, a local FM station near 100 MHz could also be heard when the receiver was tuned near 200 MHz. This was due to second harmonic generation, either in the rf amplifier of the active dipole or in the optoelectronic portion of the system. It is, therefore, advisable to check that the signals being measured are true signals and not spurious responses of the receiver system.

The use of fiber optics, with its large signal loss, demands a large amount of rf amplification. If a strong signal voltage is present, this leads to the possibility of overloading in the latter stages of the amplifier. A switchable attenuator could be incorporated in the front end of the active dipole to test for antenna overloading. Alternatively, a plug-in capacitor producing 20 dB attenuation could be fabricated to connect across each dipole gap, similar to the "outboard" resonating inductors. A design trend in broadband communications receivers for operation in strong signal environments is to eliminate the rf amplifier stage and make up the

gain in the IF amplifier. However, our active antenna system is intentionally designed for high gain and broadband, untuned operation. One apparent alternative is to use a tunable, tracking preselector, which would be a major design problem for a three-dipole isolated antenna.

As mentioned previously, the upper end of the dynamic range was defined as the point of 3 dB compression in gain. This type of non-linearity leads to desensitization by any strong signal [33]. Therefore, tests were made to determine the error introduced when a weak signal at frequency Fl must be measured in the presence of a strong signal at frequency F2. Figure 31 is a block diagram of the instrumentation used for the test and table 13 gives a summary of the data. The level of the "interfering" field at 100 MHz was adjusted in steps from 0 to 31.6 mV/m. Measurements of the "desired" signal at 75 MHz were then made to determine the effect on indicated field level, overall linearity, etc. It can be seen from the experimental data of table 13 that the tangential sensitivity and dynamic range for the weak signal at 75 MHz were not altered by the interfering signal at 100 MHz unless the interference level was greater than 10 mV/m. However, the antenna factor was changed when the interfering field was greater than 1 mV/m. When the out-of-band signal at 100 MHz was large, the receiver indication was less, causing error when using the antenna system to measure an unknown field strength.

6. DESIGN AND FABRICATION OF THE COMPLETE ISOTROPIC ANTENNA AND CONTROL UNIT

6.1 Description of the System

The three active dipoles and associated fiber-optic circuitry have been assembled and tested. Figure 32 is a photograph showing how the dipoles are mounted orthogonally with essentially a common center. The total frequency range of each induced field component is amplified and used to modulate a high-speed LED. The isotropic antenna unit is connected to three glass fiber waveguides, each 10 meters long. The auxiliary circuitry for the avalanche photodiodes, time sequencing switches, and the analog "computer" required for the RSS processing of the three dipole signals have also been designed and tested. The latter circuitry is mounted on a separate "control unit" chassis.

Figure 33 is a block diagram of the antenna control unit. Figure 34 is an interior (rear) view of the chassis showing the circuit cards and power supply. The control unit performs two major functions, namely, to (1) demodulate the rf signal from the optical carrier, and (2) calculate and display a voltage proportional to the Hermitian magnitude of the electric field. The

first function is performed by three avalanche photodiodes (APD's) that receive the infrared signals from the three antennas via glass fiber waveguides. The outputs from the three APD's are sequentially switched into the antenna input of an FIM receiver.

Figure 35 is a view of the entire field strength measuring system. It shows the isotropic antenna on a tripod, the control unit placed on top of the conventional FIM, and the three fiber guides used to convey the infrared signal between the antenna unit and the rear of the control unit.

A dc voltage from the FIM proportional to the signal-strength meter indication is returned to the antenna control unit. This voltage is processed by an analog computer to give the RSS magnitude $|\overline{v}_{in}|$, where

$$|\overline{v}_{in}| = [v_{in}^2(x) + v_{in}^2(y) + v_{in}^2(z)]^{1/2}.$$
 (12)

 V_{in} (X, Y, or Z) is the rf voltage present at the FIM antenna input port when either the X, Y, or Z APD and hence X, Y, or Z dipole is selected. The resulting voltage magnitude is displayed on a panel meter identical to the FIM panel meter, but located on the control unit chassis.

A front-panel switch is provided to select and display the output from any individual X, Y, or Z channel or the RSS magnitude. Other controls include separate photocurrent meters, gain controls, and overload indicators for each APD. Also on the front panel is an rf calibrator output supplying a -20 dBm, 5 MHz square wave signal. All interconnections are made on the back panel of the instrument. These include the three APD optical fiber inputs, the rf signal output, the FIM interface cable, three battery charger outputs, DVM outputs, and an IR source calibrator.

The following sections discuss the separate blocks in more detail.

6.2 Avalanche Photodiode Circuitry

The modulated IR signal from each LED is received and detected by a silicon APD. The circuits for the APD and bias voltage regulators are shown in figures 36 and 37, which are similar to the simplified schematic of figure 19. The APD is reverse-biased close to its breakdown voltage, specified by the manufacturer to lie between 140 and 200 volts. The APD is capable of providing internal photocurrent gain in excess of 40 dB. The gain is adjusted by varying the bias voltage. The demodulated rf signal from the APD is coupled directly to the FIM 50 Ω antenna input through the dc blocking capacitors at the output terminal of figure 36.

The APD bias regulator, figure 37, consists of three major subsections, (1) a 200 volt pre-regulator, (2) adjustable APD bias, and (3) excess photocurrent clamp. The pre-regulator drops the raw dc (280 V nominal) from the high voltage rectifier card to a regulated +200 V. The 200 V zener diode D2 provides a reference voltage to the Darlington pair emitter follower, Q1-Q2.

The adjustable APD bias current supply in figure 37 consists of transistors Q4 through Q9 and their associated components. All of the transistors are connected in Darlington pairs, thus functioning as very high beta transistors. Q4-Q5 and Q6-Q7 are connected as a "long tailed," emitter coupled differential amplifier. The 43 k Ω "long tail" resistor functions as a 3 mA current source. The 150 V Zener diode (D1 of figure 36) provides a 150 V reference voltage which is dropped by the 20 k Ω resistor (figure 37) to provide a stable +130 V to the plus input (Q4 base) of the differential amplifier. The APD bias voltage is applied to the minus input (Q7 base) through the adjustable voltage divider labeled "APD bias adjust." Q8-Q9 is a low output-impedance, emitter-follower with its base (Q8) connected to the output (Q6-Q7 collector) of the differential amplifier. The APD breakdown voltage, and hence its current gain at a fixed bias, is temperature sensitive. To compensate for this the APD bias is adjusted automatically. The temperature reference diode Dl is selected to have a breakdown voltage and temperature coefficient similar to the APD. Dl and the APD are mounted on the same thermal heat sink.

The remaining components are for the APD excess photocurrent protection circuit. The photocurrent is sensed by developing a small voltage across the 1 k Ω current-sensing resistor of figure 36. This voltage is applied to a 741 op. amp. (figure 37) operated open loop as a comparator circuit. The other input to the 741 is fixed at 300 mV. When the photocurrent exceeds 300 μ A, the voltage across the 1 k Ω sensing resistor exceeds 300 mV and the 741 output goes positive, saturating near +15 V. This in turn causes Q10, Q11, and Q3 to conduct. When Q3 conducts it drops the pre-regulator voltage to +35 V. If the photocurrent then drops below 300 μ A again, Q3 shuts off automatically, allowing the pre-regulator to reset to +200 V. An LED is provided on the front panel to indicate when an overload condition exists.

6.3 rf/IR Calibrator Circuit

As an aid in the initial setup and adjustment of the isotropic antenna system, a calibrator is provided with an rf output and also a modulated IR output for checking the APD's. The rf output is a 5 MHz square wave with strong harmonic content. The output impedance is 50 ohms. The output level across a 50 ohm load is a nominal -20 dBm at 5 MHz. The IR calibrator is a

high-speed LED identical to those used in the active antennas. It is biased and also modulated with a 5 MHz square wave. The average LED current is approximately 16 mA, the same as the LED current in the final active antenna unit.

Figure 38 is a schematic diagram of the calibrator circuit. Ql is a 10 MHz crystal-controlled oscillator. Q2 is a buffer and Q3 is a TTL logic driver. A 7474 flip-flop is used to obtain a 50% duty cycle, 5 MHz square wave. Q4-Q5 from the discrete emitter-coupled-logic, high-speed output stage. Q6 is the LED modulator.

6.4 Interface with the EMC-25 Receiver

Figure 39 shows the interface card used to mate the antenna control unit to the receiver. The rf signals from the APD's are sequentially switched into the single antenna input terminal of the receiver. Each signal is applied to the FIM one second. The complete measurement cycle takes 3.3 seconds. Switching is done by small reed relays K3, K4, and K5.

The EMC-25 provides a dc output voltage V_0 across a 1.5 k Ω , 1% resistor in the inter-tie cable that is proportional to the signal strength meter indication (1.5 volts full scale). A separate cable is used to connect this "output meter" voltage and the EMC-25 "dump" control signal to the isotropic antenna control unit. The meter dial indication is in terms of rf microvolts at the FIM antenna input cable. A second meter scale is linear in dB above 1 μ V.

The basic measurement cycle time of one second for each field component (X, Y, or Z) is fixed by the slow response time of the EMC-25 receiver. Figure 40 shows examples of the FIM response, V_0 , to various-length rf pulses for, respectively, the "carrier," "quasi-peak," and "peak" modes of detection. In the carrier mode the 0%-98% rise time is 0.6 s while the 100%-2% fall time is 1 s. For quasi-peak detection the risetime is 6 ms while the fall time remains at 1 s. For peak detection the risetime is only a few microseconds. The discharge characteristics are determined by the DUMP control. With the DUMP control fully ccw and into the switch detent the circuit is in a hold mode with a fall time in excess of 10 s. With the DUMP control ccw the meter reading is held for a dump delay of 300 ms and is then discharged rapidly. The minimum dump delay is 20 ms when the control is cw.

The two op. amps. of figure 39 are used as a peak detector to hold the maximum meter deflection V_{O} during each measurement time interval (X, Y, or Z). The peak detector is reset to zero at the end of each measurement interval by relay Kl. At the same time relay K2 provides a contact opening to "dump" the EMC-25 output meter circuit when the FIM is operated in the PEAK mode.

6.5 Vector Magnitude Analog Computer

The vector magnitude of the X, Y, and Z inputs to the FIM is determined by an analog computer that consists of three circuit boards, figures 41, 42, and 43. Operational amplifiers, an antilog integrated circuit (IC), sample and hold circuits, an analog multiplier IC, and a logarithmic amplifier IC are used to calculate a voltage according to eq. (12). The following discussion presents in detail the various mathematical operations performed.

The FIM output meter voltage V follows the equation

$$V_{0} = 1.05 + 0.45 \log_{10} [V_{in}(\mu V)/1 \ \mu V] \text{ volts.}$$
(13)

Thus for $V_{in} = 10 \ \mu V$, $V_o = 1.5 \ V$; for $V_{in} = 1 \ \mu V$, $V_o = 1.05 \ V$; for $V_{in} = 0.1 \ \mu V$, $V_o = 0.6 \ V$; and for $V_{in} = 0.01 \ \mu V$, $V_o = 0.15 \ V$. The maximum meter voltage during each sample time is detected and held in the EMC-25 interface, where

$$V_{\rm om} = V_{\rm o} \,({\rm max}) \,. \tag{14}$$

The first op. amp. of figure 41, IC-1, is simply a high input impedance buffer such that

$$V_1 = V_{om}.$$
 (15)

IC-2 of figure 41 provides signal inversion, amplification and level shifting to obtain

$$V_2 = -2.22 V_1 + 3.33$$
 (16)

=
$$1 - \log_{10} [V_{in}(\mu V) / 1 \mu V]$$
 volts. (17)

IC-3 is an antilog IC that is used to extract a voltage proportional to the FIM input voltage (in μV) squared. That is,

$$V_3 = V_{ref} 10^{-(V_2/K)}$$
 (18)

The circuit constants are chosen to give

$$v_{ref} = 10 V,$$
 (19)

$$K = 0.5$$
 (20)

thus producing a voltage V2 given by

$$V_{3} = \frac{1}{10} [V_{in}(\mu V) / 1 \ \mu V]^{2} \text{ volts.}$$
(21)

Thus at this point we effectively have V_{in}^2 .

The next step is to obtain the summation of $v_{in}^2(X)$, $v_{in}^2(Y)$, and $v_{in}^2(Z)$. This is accomplished by first storing $V_3(X)$, $V_3(Y)$, and $V_3(Z)$ in three separate sample-and-hold circuits, IC-4, 5, 6 in figure 41. The output voltages are

$$V_4 = V_3(x) \propto V_{in}^2(x)$$
 (22)

$$V_5 = V_3(Y) \propto V_{in}^2(Y)$$
 and (23)

$$V_6 = V_3(Z) \propto V_{in}^2(Z)$$
 (24)

These voltages are algebraically added in the op. amp. adder IC-7 of figure 42 to obtain V_7 , given by

$$v_7 = -\frac{1}{3}(v_4 + v_5 + v_6)$$
⁽²⁵⁾

$$= \left(\frac{-1}{30}\right) \left[\left(\frac{V_{in}(X)}{1 \mu V}\right)^{2} + \left(\frac{V_{in}(Y)}{1 \mu V}\right)^{2} + \left(\frac{V_{in}(Z)}{1 \mu V}\right)^{2} \right].$$
(26)

IC-8 is simply an inverter, so

$$V_8 = -V_7.$$
 (27)

IC-9 is an analog multiplier connected to perform the square root operation,

$$v_9 = -\sqrt{10} v_8$$
 (28)

$$= -\sqrt{\frac{1}{3}} \left[\left(\frac{V_{in}(X)}{1 \mu V} \right)^{2} + \left(\frac{V_{in}(Y)}{1 \mu V} \right)^{2} + \left(\frac{V_{in}(Z)}{1 \mu V} \right)^{2} \right]^{1/2} .$$
 (29)

IC-10 is an inverter, so

$$v_{10} = -v_9.$$
 (30)

 $V^{}_{\mbox{l0}}$ is sampled by K4 each second and held by the 0.1 μF capacitor and IC-ll. That is

$$V_{11} = V_{10}$$
 (sampled). (31)

 V_{11} is the desired answer and is linearly proportional to $|\overline{V}_{in}(\mu V)|$ in equivalent microvolts. The EMC-25 meter scale is linear in dB μV , thus V_{11} must be processed by a log circuit, IC-12 of figure 43, before driving the meter. Thus

$$V_{12} = -\log_{10} (V_{11}/5.77 \text{ V}). \tag{32}$$

The meter on the control unit panel is driven by IC-13 according to the equation

$$I(meter) = -0.3 V_{12}(volts) + 1 mA.$$

In addition to the front panel meter shown in figure 43, two outputs are available on the back panel for connecting an external digital voltmeter (DVM). IC-14 provides an output proportional to dBµV while IC-15's output is proportional to µV. These voltages are given by

$$V_{14} = -2 V_{12} + 2, (34)$$

$$V_{15} = 0.173 V_{11}.$$
 (35)

Table 14 lists the voltages throughout the analog computer for various rf input voltages. As can be seen from the table, for antenna input voltage below 0.1 μ V, the squaring process yields values for V₇ in the microvolt region. Due to noise, drifts, offsets, etc., in the analog computer these low level signals are useless. To obtain accurate field strength measurements, the rf signals should be greater than 1 μ V.

6.6 X-Y-Z Measurement Sequencer

The measurement sequencer board, figure 44, provides the timing and control signals for the interface circuits and the analog computer. As discussed previously, the 3.43 s measurement cycle time is fixed by the slow response time of the FIM. Figure 45 shows the important control signals and their timing relationship. Figure 46 shows the internal signals within the measurement sequencer. CMOS integrated digital logic is used.

An internal clock is provided which consists of a 555 timer, IC-1, and two flip-flops, IC-2 and 3. The 555 timer produces a pulse train at 28 Hz. The flip-flops produce square waves at 14 Hz and 7 Hz.

The X, Y, Z pulses are the antenna channel selectors. Each pulse is of 1 s duration. These pulses are generated by three 8-bit shift registers, IC-6, 7 and 8. A measurement cycle is started by a LOAD pulse which loads the data words X = 1111110, Y = 00000000, and Z = 00000000 into the shift registers. The 7 Hz square wave, CLK, then sequentially shifts these words out of the shift registers. As CLK repeats, a "0" on the serial input to IC-6 is shifted in until the first register is full of all "0"s. The output of the first register, X, is the serial input to the second register, IC-7. Thus 8 CLK pulses later in time the X word appears as the Y pulse. The same thing occurs for the last register, IC-8, to generate the Z pulse.

With the particular data word selected for X, a dead time of one CLK period (1/7 second) is provided between the X, Y, and Z pulses. During this time interval the peak detectors on the interface board of figure 39, and in the EMC-25 receiver, are discharged. This is accomplished through the DUMP pulse. A NOR gate IC-18 determines when X, Y, and Z are all "0"s. In the middle of the DUMP pulse a SAMPLE (1S) pulse is produced to activate the sample and hold relay in the analog computer, K4 in figure 42. This is a 1/28 second pulse selected by the NOR gate IC-17 when DUMP, CLK, and CLKX2 are all "0"s. The DUMP and SAMPLE (1S) pulses occur three times during each measurement cycle.

At the end of the measurement cycle the shift registers must be reloaded. Figure 46 shows the various signals required to generate a LOAD pulse. The negative-going transition of Z is inverted by IC-9 of figure 44 and used to clock the D type flip-flop IC-4. The D input was a "1," thus the flip-flop \overline{Q}_1 is toggled to a "0." This "0" applied to the NOR gate IC-14 allowed it to pass a 1/28 second pulse when flip-flop \overline{Q}_1 , CLK, and CLKX2 are all "0"s. This pulse is labeled SAMPLE (3S) and is used to set the next flip-flop IC-5. SAMPLE (3S) can be used to control the analog computer sample-and-hold if a new meter reading is desired only every 3-1/2 seconds. When flip-flop Q_2 is set, this enables the NOR gate IC-15 to generate a 1/28 second LOAD pulse when flip-flop \overline{Q}_2 , CLK, and CLKX2 are all "0"s. The positive-going transition of LOAD is used to clock a "0" into the flip-flop Q_2 (IC-5), thus resetting it.

The above discussion describes all sequences in a normal measurement cycle. However, at power turn-on time it is possible for either or both of the flip-flops, IC-4 and IC-5, to latch up in the wrong state. If this occurs, a LOAD pulse would not be generated, thus resulting in X, Y, and Z all remaining at "0." To alleviate this problem a train of several LOAD pulses is generated for one second after the power is turned on. This is accomplished by interrupting the connection of flip-flop IC-5 into the LOAD NOR gate IC-15 with an alternate gating pulse, START. An RC delay circuit (1 M Ω , 1 μ F) is connected to the +5 V line. This RC circuit delays applying a "1" to the input of inverter IC-11 for approximately one second. Thus the output of the inverter is the 1 second START pulse. The NOR gate IC-16 is used to route either the START pulse or the Q₂ output of IC-5 into the LOAD NOR gate, thus always assuring several LOAD pulses at turn-on time.

6.7 Auxiliary Equipment

Figure 47 is a schematic diagram of the battery charger for recharging the 9.6 V Ni-Cd batteries in the active antennas. The circuit consists of three 15 mA constant-current sources with over-voltage protection provided by the 13 V Zener diode. The three diodes at the charger output terminals are used to prevent the batteries from discharging back into the charger when the ac power is turned off.

The high voltage (280 V) supply for the APD bias regulator is shown in figure 48. The ± 15 V supply is shown in figure 49. It is an ordinary regulated power supply. The only special requirement is that the voltages must be precisely set to +15.00 V and -15.00 V because they are used as reference voltages in the analog computer. Deviations in these voltages will affect the computer accuracy.

Figure 50 is a diagram showing the interconnecting cables between the antenna control unit, the rf/IR calibrator, and a conventional EMC-25 receiver.

A complete parts list and detailed instructions for proper alignment of the electronic circuitry in the control unit have been furnished to ECOM in a separate manual.

7. SUMMARY AND CONCLUSIONS

A broadband isotropic antenna system was developed for measuring rf emanations in a screen room environment. It uses a fiber-optic link between the electrically-isolated antenna unit and a conventional EMI receiver. The frequency range of interest is 15 kHz to 200 MHz. Above this frequency the optoelectronic link suffers severe rolloff in response. However, at these higher frequencies it is possible to use "hooded" antenna techniques and anechoic chambers. The NBS active antenna consists of 3 mutually orthogonal dipoles and responds to arbitrary polarization, which decreases some of the difficulty encountered in screen room measurements. Each of the dipoles is 31 cm long x 3.5 cm diameter and contains an rf amplifier, electroluminescent diode (LED), and a battery. The dipole is electrically short at all frequencies, thus achieving a sensor with wide bandwidth. The antenna has high sensitivity (up to 10 μ V/m) and does not require tuning.

The signal picked up by each dipole is applied to a FET-input rf amplifier which modulates the infrared (IR) intensity of a solid-state LED. The IR radiation, which is injected into the end of a glass fiber waveguide, is thus modulated with all signal frequencies within the system bandwidth. The far end of each guide is optically coupled to an avalanche photodiode (APD) in the "control" unit, which recovers the rf modulation from the IR carrier. Each of the 3 fiber guides is 10 m long, thus isolating the antenna electrically from the equipment under test and the enclosure walls. The 3 recovered rf signals are applied to the EM receiver through a time sequencing switch, sample-and-hold circuitry, and RSS processing. The one indication on the field strength readout meter is proportional to the Hermitian magnitude of the electric field.

The present antenna system uses an incoherent LED for the IR source, a silicon APD for the photodetector, and a multimode glass fiber bundle for the transmission line. Compared with lasers, LED's are slow (5 to 10 ns rise-time), have relatively large spectral width (30 to 40 nm) and large beam divergence (about 30°). The slow response time limits the analog bandwidth in the antenna to about 150 MHz. The large beam divergence makes it difficult to couple the LED output into the end of the fiber, causing coupling losses of 20 to 25 dB. The APD used has a gain-bandwidth product of 100 GHz, so it is not the limiting factor for high signal frequencies. The rolloff in sensitivity at frequencies above 150 MHz is quite steep and is due mainly to limitations of the LED source. An attempt was made to use current state-cf-the-art technology for the fiber-optic link and antenna system. The overall system was designed to be compatible with an ECM-25 type of FIM.

New technologies employing laser diodes, single-mode fibers, and integrated-circuit optical components may eventually provide the answer to the search for an EMI antenna with huge bandwidth and high sensitivity. However, the only battery-operated source available for our project, which was compatible with fiber optics, was the incoherent LED. It is small, light, rugged, reliable, inexpensive, and (most important) is easy to modulate with an rf signal. It can be battery operated with low voltage and low current. The data presented in this report are believed to represent the optimum performance for a non-lasing diode at the time of this project.

The initial tests for choosing the optimum components and improving the circuit design were made by both time-domain and frequency-domain techniques. In general, the testing of optoelectronic components was done by observing pulses on a sampling oscilloscope. The preliminary design of the circuitry was optimized by observing swept-frequency results on a spectrum analyzer. Later refinements were then accomplished at discrete frequencies by immersing the active dipole in a known field and checking the performance characteristics

The rf open-circuit pickup of a 31 cm dipole is quite low and the signal is further reduced by the impedance mismatch between the short antenna and the rf amplifier. The sensitivity of the antenna system developed at NBS is adequate for signal frequencies below 25 MHz. At higher frequencies the bandwidth of the receiver used is larger (50 kHz) and the sensitivity is generally below that required for making MIL-STD-461 measurements. The circuitry of the rf amplifier incorporates frequency compensation to accentuate the signals above 50 MHz, thus compensating for some of the LED rolloff at these higher frequencies. Also, small toroid inductors were designed to be connected across the center gap of each dipole. The resulting antenna resonance increased the sensitivity enough to meet the specifications up to a frequency of 150 MHz.

The antenna factor vs. frequency for the fiber-optic antenna was determined by calibrating the individual dipoles in the known field of a TEM transmission line. For our project the antenna sensitivity was defined as the field intensity required to increase the receiver indication 3 dB above the system noise level; that is, the tangential sensitivity. The ultimate sensitivity of any measurement system is set by the noise accompanying the signal, and therefore by the system bandwidth. Using an EMC-25 receiver, the fiberoptic antenna system essentially satisfied the sensitivity requirements for measuring narrowband fields according to MIL-STD-461 up to a frequency of 150 MHz. The linear dynamic range of the antenna system was defined as the difference between the tangential sensitivity and the field level causing 3 dB compression. The dynamic range of the fiber-optic antenna system varied from 70 dB at a signal frequency of 20 kHz to about 50 dB at a frequency of 150 MHz.

Acceptable performance of an infrared (LED/fiber guide/APD) antenna system requires a combination of high sensitivity, low noise, large bandwidth so no antenna tuning is required, and large dynamic range so the distortion is low. Engineering tradeoffs were made in an attempt to achieve optimum overall performance. The high-sensitivity system developed at NBS is somewhat restricted by the low dynamic range of the system. The antenna is thus most suitable for measurement of weak signals. When measuring a strong field it is advisable to insert an attenuator in the rf amplifier. Also, the present active antenna becomes desensitized by any one strong signal in the total frequency range; this may cause error in the measured field strength of a weak signal in the presence of a strong out-of-band signal.

It was not possible to demonstrate experimentally the degree to which the antenna response pattern is truly isotropic. NBS does not have an anechoic chamber for measuring antenna patterns below 1 GHz, and calibration at an outdoor field site was hampered by large ambient signals from local AM and FM stations. However, from past experience in evaluating the response vs. orientation angle for microwave hazard probes, which also employ 3 orthogonal dipoles in the rf sensor, it is known that an isotropic response is achieved if the dipoles have separate responses which are equal and if accurate signal processing is used to obtain the Hermitian magnitude. The three dipoles in the engineering prototype antenna delivered to ECOM were adjusted for equal response at a frequency of 25 MHz and a field level of 100 μ V/m. The required alignment procedure for the antenna, a parts list, and a set of schematic diagrams were furnished to ECOM in a separate instruction manual.

It is not possible to measure a single transient pulse of interference with the time sequencing approach used here because the metering unit does not sample the output of all 3 dipoles simultaneously. The reception and measurement of impulse interference caused by <u>repetitive</u> pulses can be accomplished, however, even when time sequencing the X-Y-Z field components. One procedure to insure pickup of an isolated pulse of unknown polarization would be to use three separate EMI receievers, although this is not an economical approach.

In conclusion, we have developed a sensitive, isotropic, electricallyisolated antenna, using commercially-available fiber-optic technology. The antenna can be used to measure weak steady-state emanations in a shieldedroom environment. It was found that an infrared system employing LED sources, multimode glass fiber transmission lines, and avalanche photodiode. detectors can offer certain improvements over a more conventional antenna. Some of the problems relating to fiber-optic technology have not yet been solved, and should receive further development work. However, the basic concept of an isotropic EMI antenna has been verified. Newer and better components and techniques, such as integrated optics and solid-state laser diodes, could lead to significant improvements in performance.

8. RECOMMENDATIONS AND FUTURE PLANS

The results achieved in this NBS/ECOM program have been very encouraging in nearly all aspects. The concept of measuring field strength with an active isotropic antenna using a fiber-optic link to the EMI receiver has been demonstrated. In view of certain advantages gained by this type of isolated probe, it would be highly desirable to continue this research effort, evaluating additional opto-electronic components and hardware for improving the measurement system. Also, it might be possible to simplify some of the circuitry, alignment procedure, and technique for measuring absolute field strength; these now require a fairly high degree of skill. It would then be possible to fabricate a general purpose EMI antenna with a more repeatable antenna factor and a greater dynamic range.

In particular, it is suggested that a more thorough evaluation be made of a new type of "high speed" LED which became available recently [34 and 35]. One of these LED's was checked briefly at signal frequencies from 25 to 200 MHz. The overall performance (tangential sensitivity, linearity and dynamic range) was no better than the LED used in our project. In fact, at the upper frequency end of the spectrum (150 to 200 MHz) the sensitivity was worse by about 2 dB. This type of LED has a specified frequency rolloff of only 3 dB at 200 MHz. Our measured rolloff was much greater. However, the new LED was tested for only one value of bias current (16 mA) which may have been too low to achieve the expected high frequency improvement.

NBS thus recommends a follow-on program in which the existing isotropic antenna and control unit are more thoroughly evaluated in order to establish the optimum procedure for measuring absolute field strength. Additional development work could then be initiated if that is considered advisable. Another possible investigation would be to evaluate the new GaAlAs <u>laser</u> diodes which have just become available. These are solid-state replacements for bulkier and less efficient gas lasers. They have a specified risetime of only 0.1 ns, beam spread of only 5° and spectral width of only 2.5 nm, with peak emission at 850 nm. However, the specified minimum forward current is about 150 mA, so they would require frequent battery replacement or other means of supplying power to the isolated antenna.

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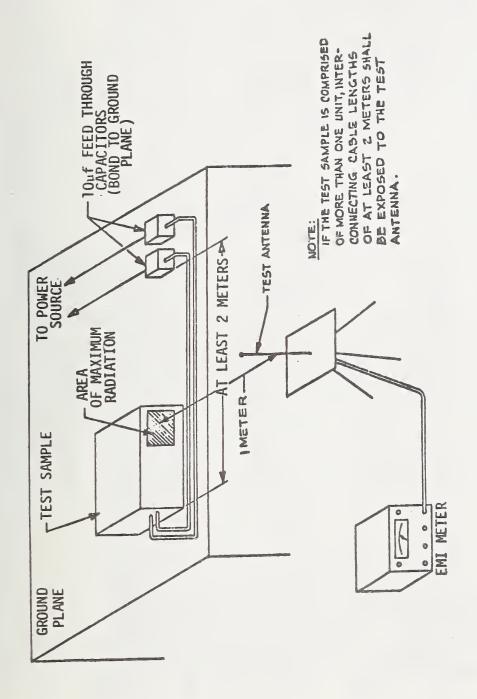
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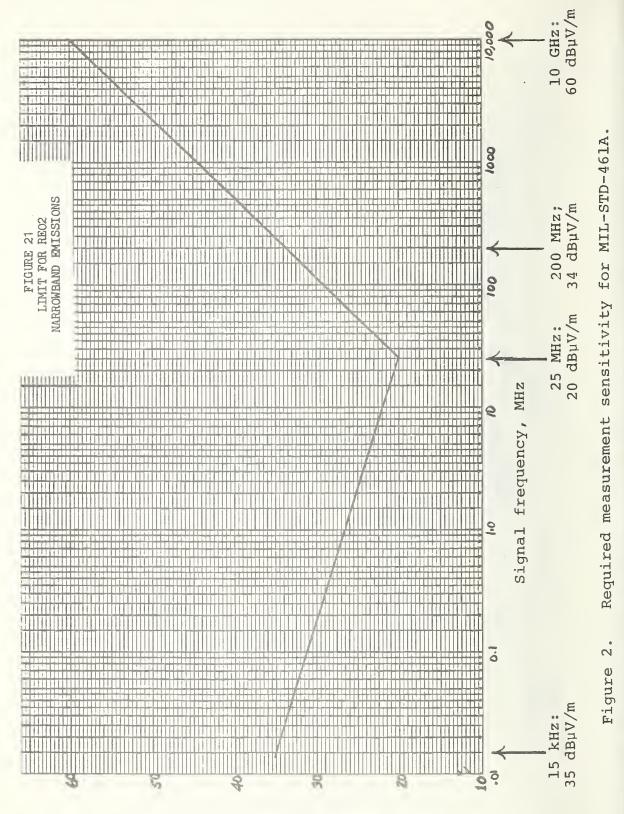
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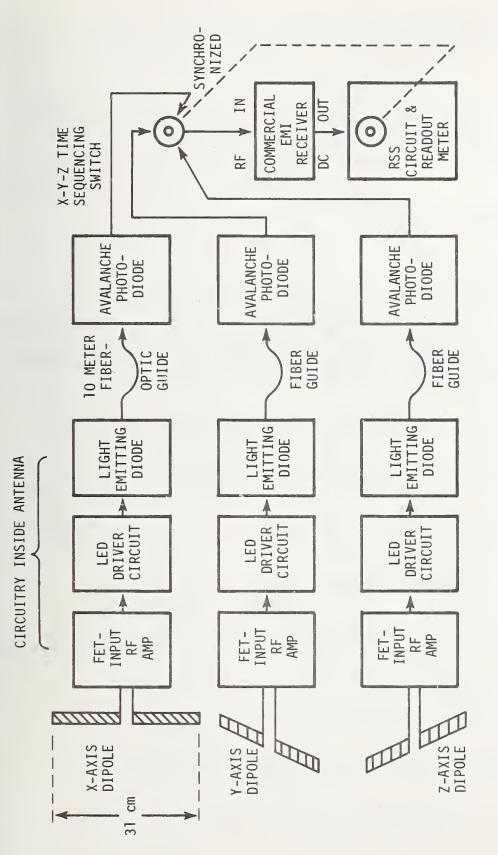
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Typical test setup for measuring radiated emissions, MIL-STD-461A, RE02. Figure 1.



Radiated E field, dByV/m



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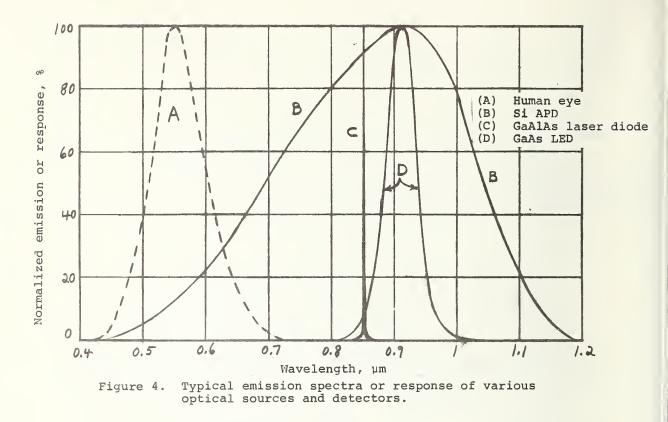
isotropic, fiber-optic Block diagram of the broadband, antenna system developed at NBS. Figure 3.

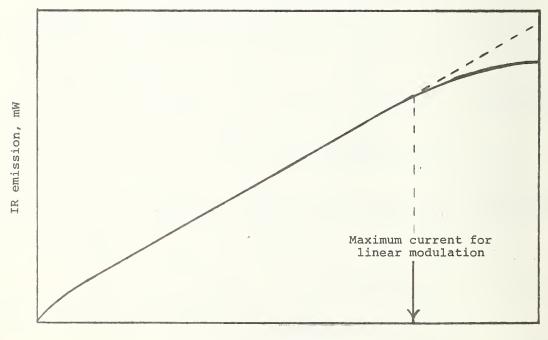
Table 1. Sensitivity requirements for measuring narrowband signals according to MIL-STD-461/462.

Signal	MIL-STD-461/642 E Field Limits		Open-Circuit Pickup of a 31 cm	Approximate Receiver	
Frequency	dBµV/m	µV/m	Dipole \approx 0.15 E	Input	
15 kHz	35.0	56	8.4 µV	4.2 μV	
100 kHz	31.2	36	5.4	2.7	
l MHz	26.5	21	3.2	1.6	
10 MHz	21.9	12	1.9	0.9	
25 MHz	20.0	10	1.5	0.8	
100 MHz	29.1	29	4.3	2.1	
200 MHz	33.7	48	7.3	3.6	
l GHz	44.5	168			
10 GHz	60.0	1000			

Table 2. Characteristics of fiber-optic and radiated infrared communication links.

Advantages:	Large information bandwidth					
	High security, low cross-talk and pickup					
-	Freedom from EMI, no E or H coupling					
	Electrical isolation, absence of ground loops					
	No short circuits, arcing or grounding problems					
	Components are small, lightweight, and low power					
-	Transmission lines are light, flexible and low loss					
	For radiated links: large antenna gain, no license required					
	Will eventually be cheaper than coax or radiated rf links.					
Disadvantages:	Shortage of off-the-shelf opto-electronic com- ponents					
	Glass fibers are difficult to splice and are not rugged to handle.					
Proposed Uses:	Outer space and aircraft applications (lightweight)					
	Military airplanes and ships (high security)					
	Inter and inner city trunk lines (large bandwidth)					
*	Electrically isolated links for EMI antennas and rf hazard probes.					





Forward current, mA

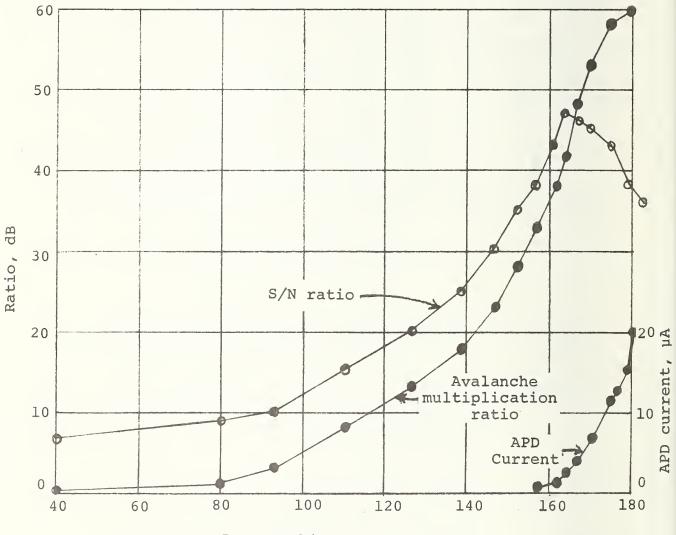
Figure 5. Intensity of radiation vs. forward current for a typical infrared LED.

Type Number	* 471	31	3	930	4120	2430	6478
Forward bias current, mA	150	100	50	100	100	150	3000
Radiated power output, mW	1	6	0.8	0.65	0.2	0.3	300
Peak emission wavelength, nm	910	940	900	900	890	907	935
Spectral bandwidth at 50% of peak intensity, nm	23	60	50	40	35	22	
Beam spread at 50% of peak intensity, degrees	130	10	56	30	90	32	180
LED emitting diameter, mils	18				24		
10%-90% risetime, ns	15	600	1		100	20	700

Table 3. Specified CW characteristics of some typical LED's.

Table 4. Specified characteristics of some typical photodetectors.

Type Number	30807	2	4220	3421	30817	59	★ 451	7102 (Tube)
Type of device	Si PIN diode	Si PIN diode	Si PIN diode	Si PIN diode	Si APD	Si APD	Si APD	Photomul- tiplier
Responsivity, µA/µW	0.65	0.7	0.5	0.55	80	24		400
Peak spectral response, nm	900	900	770	890	900	770	850	800
Spectral bandwidth at 10% points	400- 1100	310- 1140	400- 1040	420- 1100	420- 1100	550- 960	550- 1100	
Active reception area, mm ²	0.8	0.58	0.2	1.3	0.5	0.45	0.45	780
Current amplification factor	1	1	1	1	120	120	200	150,000
Noise equivalent power, pW/Hz	0.1				0.01	0.2	0.2	
10-90% risetime, ns	3	0.5	< 1	< 5	2	< 10	< 10	25



Reverse bias on APD, volts

Figure 6. Measured performance of avalanche photodiode No. 2 at an ambient temperature of 28°C.

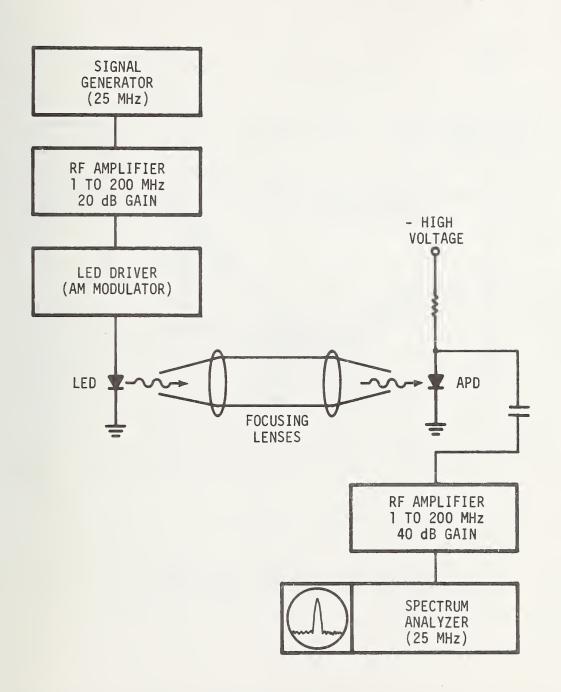
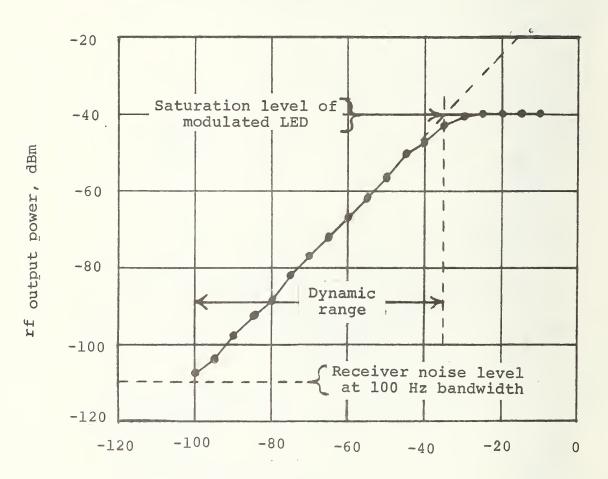


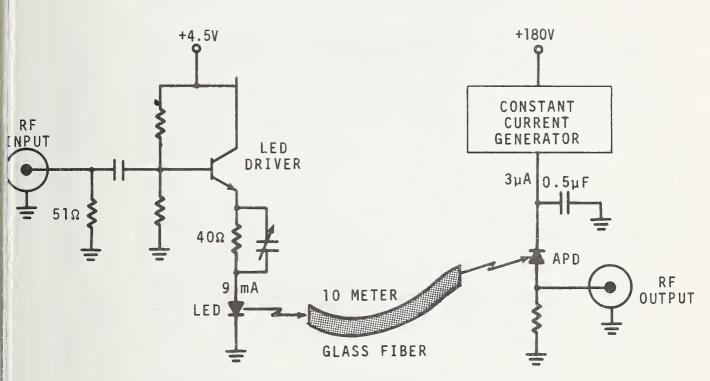
Figure 7. Instrumentation for an experimental radiated communications link.



rf signal input power, dBm

Figure 8.

8. Performance of the experimental radiated link at a signal frequency of 25 MHz.

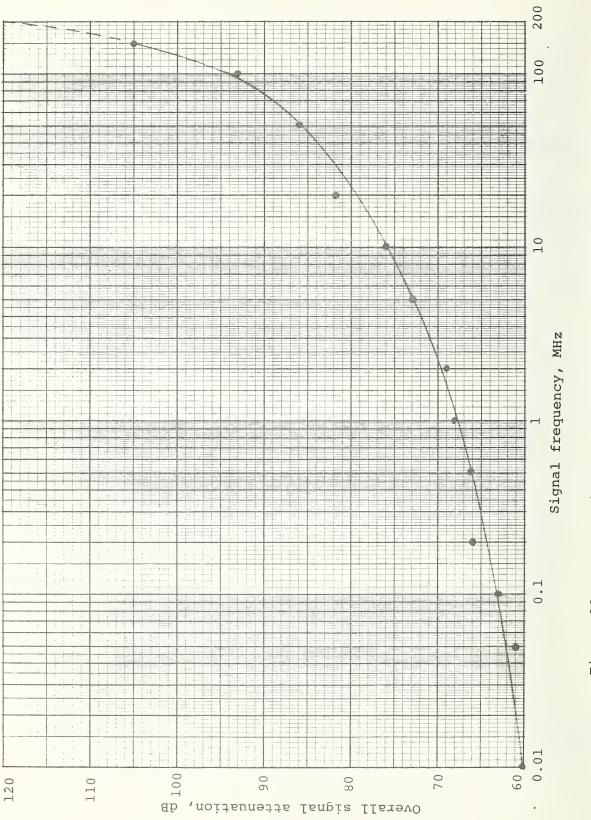


rf signal attenuation at low frequencies:

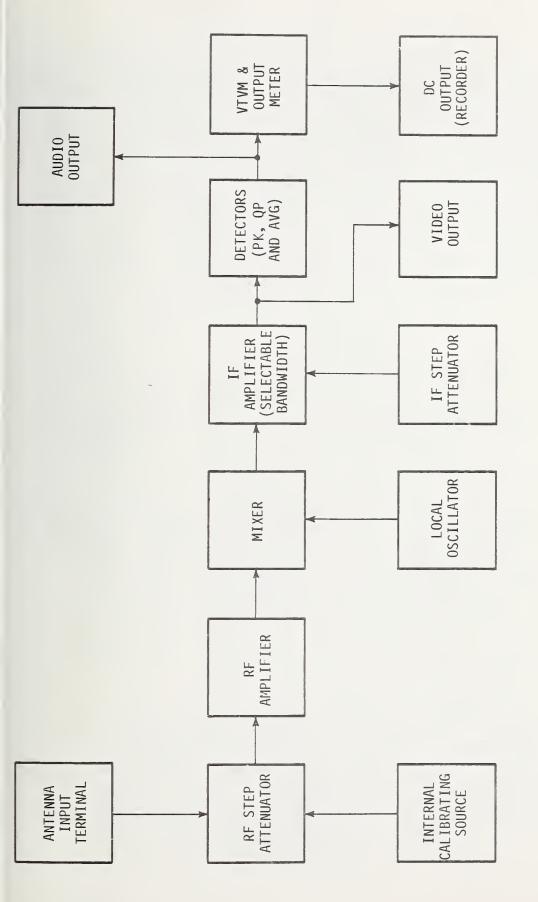
LED	alone75	dB	loss
APD	alone60	dB	gain
	and APD15		
	er coupling45		
LED/	fiber/APD system60	dB	loss

Figure 9.

Simplified schematic of the instrumentation for measuring rf attenuation of the fiber-optic link.



Attenuation vs. frequency of the fiber-optic system. Figure 10.



Block diagram of a typical EMI receiver. Figure 11.

		ender dillerunden gehannen oppag dass als eine fins das den der die "eine der die der die der die der die der d	Nominal Bandwi			ential itivity
Receiver Band Number	Frequency Range	Intermediate Frequency	NB	WB	NB(CW) (μV) ·	WB(Impulses) (dBµV/MHz)
1 2 3 4 5 6 7 8 9 10 11 12 13	14.0-28.5 kHz 28.5-59 kHz 59-120 kHz 120-240 kHz 240-480 kHz 0.48-1.05 MHz 1.05-2.3 MHz 2.3-5 MHz 5-11 MHz 11-25 MHz 24-49 MHz 49-98 MHz 98-210 MHz	175 kHz 175 kHz 175 kHz 175 kHz 175 kHz 175 kHz 175 kHz 175 kHz 1.6 MHz 1.6 MHz 1.6 MHz 1.6 MHz 8.7 MHz 8.7 MHz 8.7 MHz		4 kHz 4 kHz 4 kHz 4 kHz 5 kHz 5 kHz 50 kHz 50 kHz 500 kHz 500 kHz 500 kHz	0.06 0.06 0.06 0.06 0.06 0.06 0.12 0.12 0.12 0.12 0.12 0.80 0.80 0.80	39 39 39 39 39 39 39 39 38 22 22 22 20 20 20 23

Table 5. Specified characteristics of the EMC-25 receiver.

Table 6. Bandwidth of the EMC-25 FIM receiver in narrowband selectivity position.

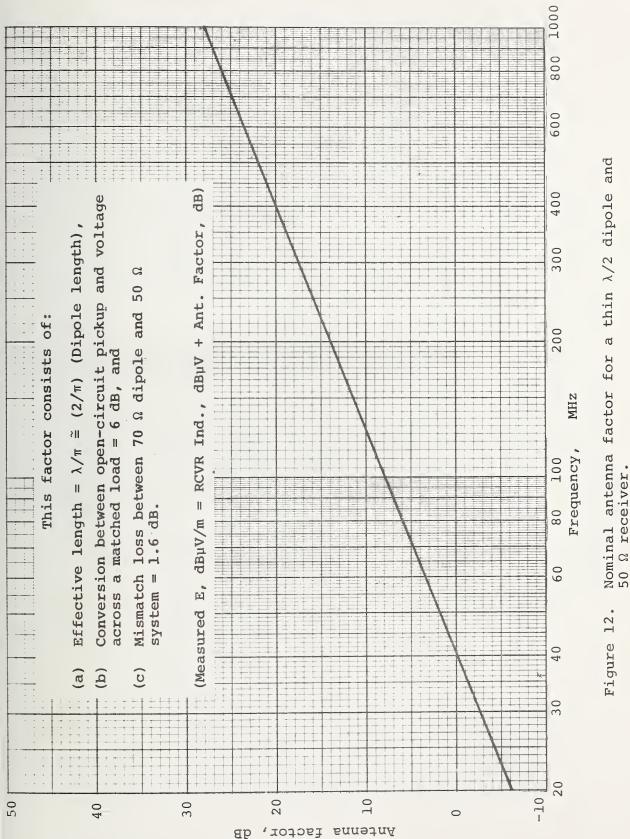
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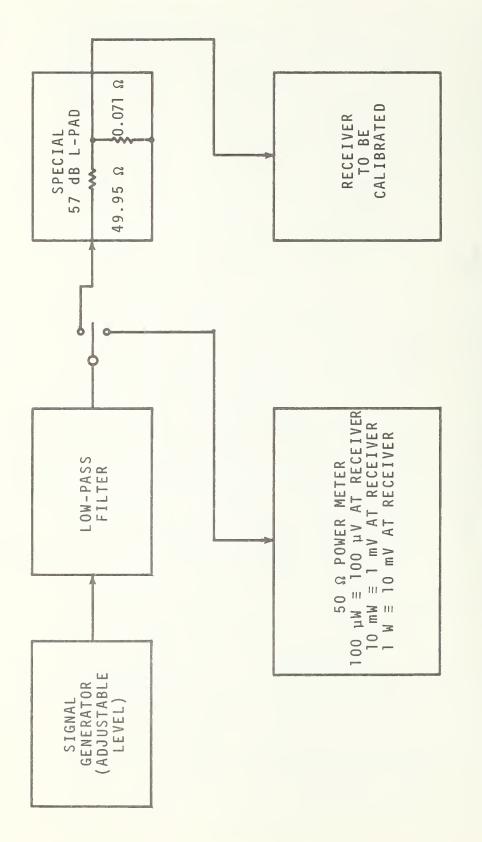
(a) Bandwidths according to the manufacturer:

Band	Frequency	Nominal	
Number	Range	Bandwidth	
1 to 7	14 kHz to 2.3 MHz	500 Hz	
8 to 10	2.3 to 25 MHz	5 kHz	
11 to 13	24 to 210 MHz	50 kHz	

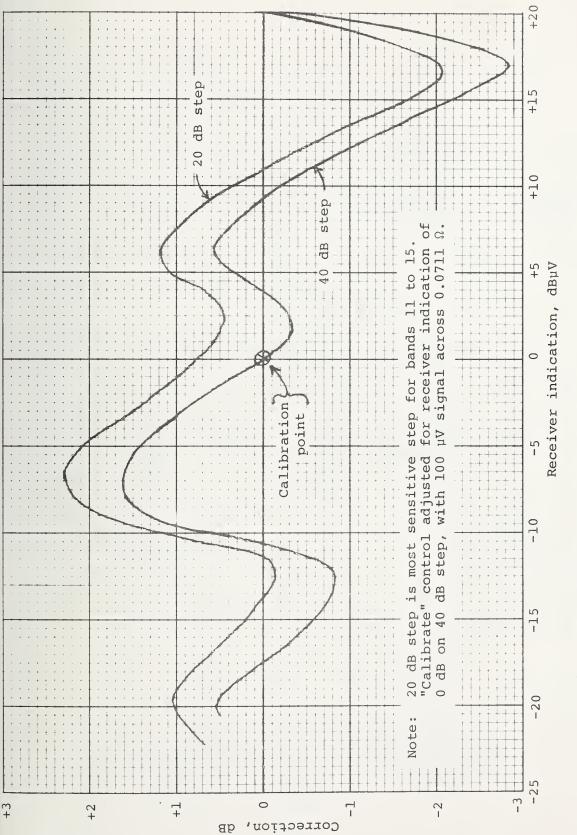
(b) Measured bandwidths:

Band	Receiver	Signal Frequency for	-3 dB
Number	Frequency	-3 dB Indication	Bandwidth
1	15 kHz	14.676-15.350 kHz	0.67 kHz
3	100 kHz	99.742-100.312 kHz	0.57 kHz
7	2.3 MHz	2.29974-2.30029 MHz	0.55 kHz
8	2.3 MHz	2.29754-2.30256 MHz	5.0 kHz
10	25 MHz	24.99758-25.00280 MHz	5.2 kHz
11	25 MHz	24.96805-25.02701 MHz	59 kHz
13	200 MHz	199.9738-200.0268 MHz	53 kHz.

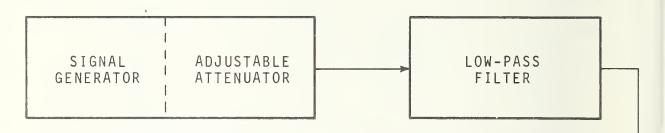




Instrumentation for calibrating a receiver to measure CW voltage. Figure 13.



Linearity of the receiver used (EMC-25, band 11, narrow bandwidth, 25 MHz). Figure 14.



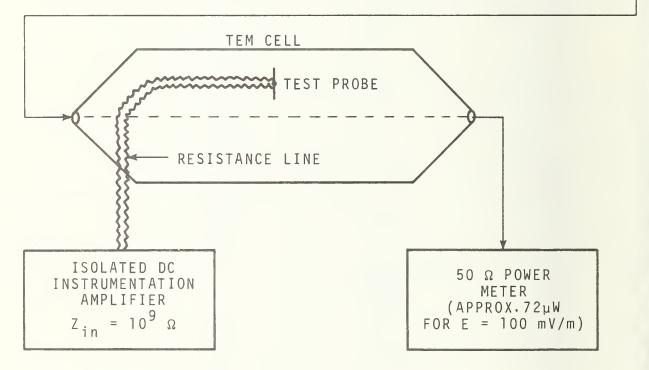
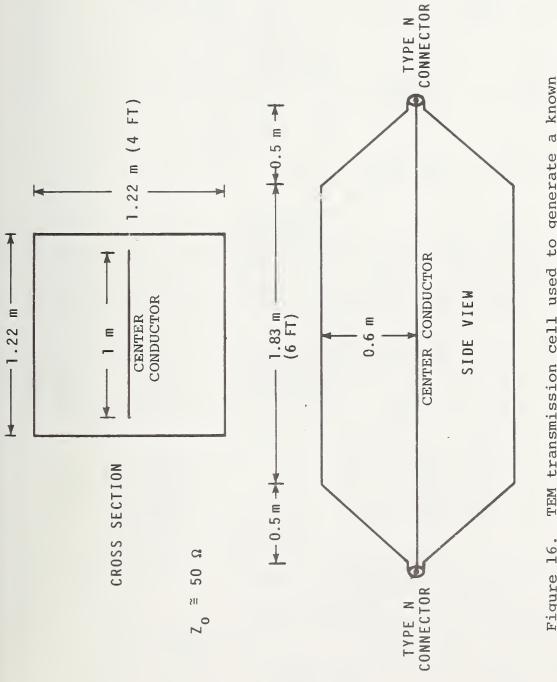
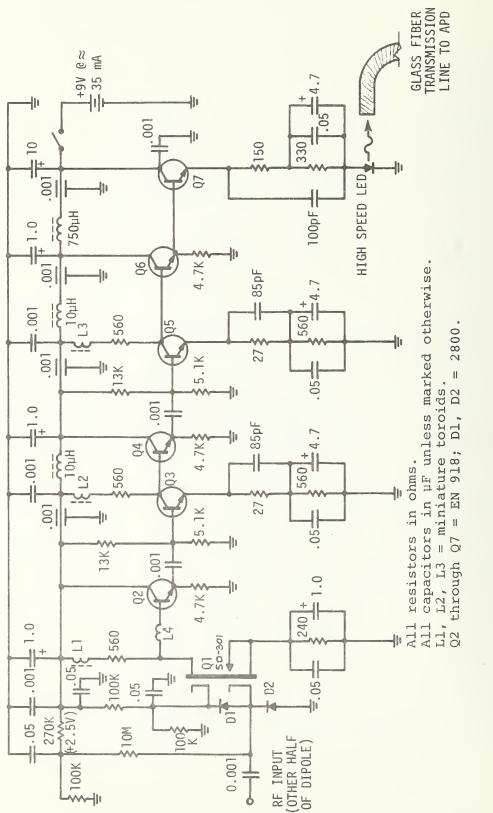
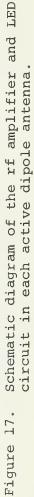


Figure 15. Instrumentation used to establish a known E field in the TEM cell for calibrating the active dipole.









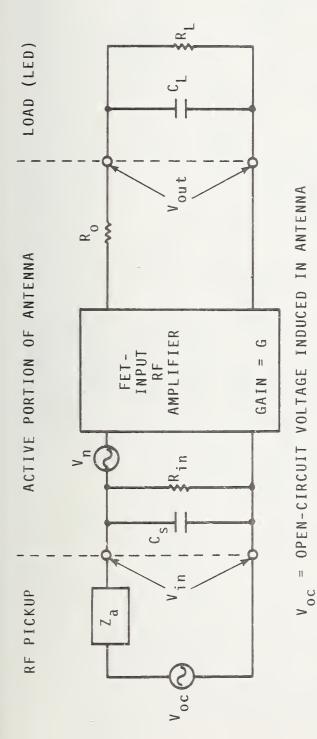
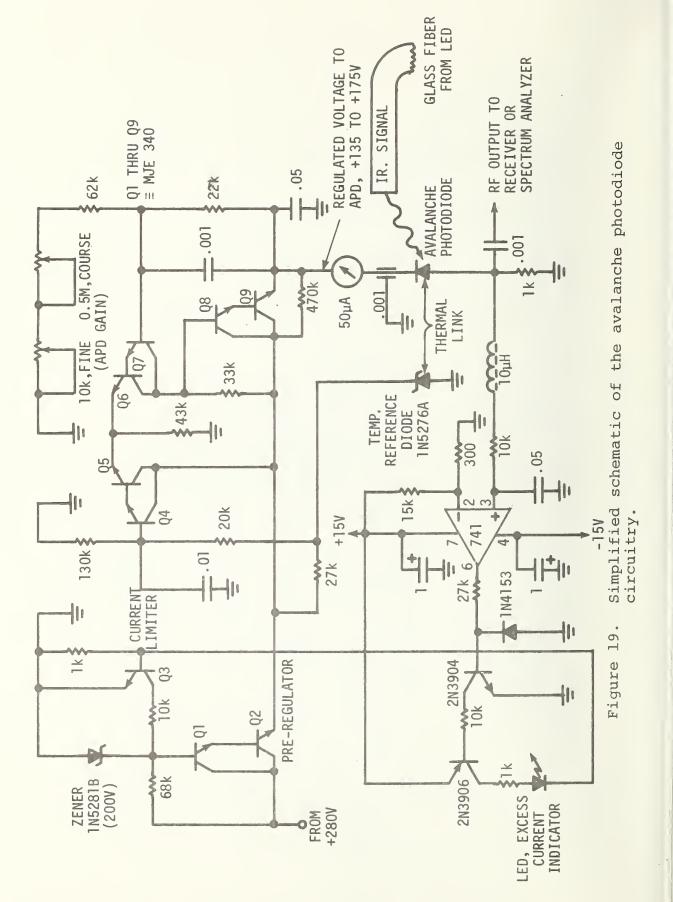


Figure 18. Equivalent circuit of the active antenna.



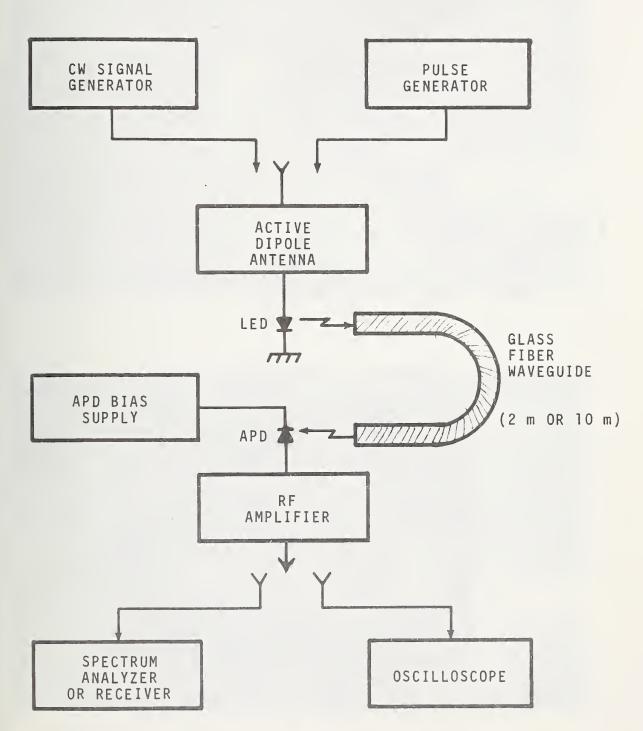


Figure 20. Test setup for observing the system gain, frequency response and step response.

Table	7.	Frequency response test of the prototype antenna	
		system. (Input signal = -80 dBm, Spectrum analyzer	
		pandwidth = 3 kHz.)	

Frequency, MHz	Gain, dB	(S+N)/N ratio, dB
15 25	16 16	20 20
50 75	15	19 18
100 125	5	16 12
150	-3	10
175 200	-4 -6	8 6



Figure 21. Signals received in the laboratory by a prototype active dipole. (Horizontal scan from DC to 200 MHz, spectrum analyzer bandwidth = 3 kHz.)





Figure 22. Degradation of TV picture caused by the fiber-optic link.

2 m long.) .N/(N+S) the given receiver indication ١, type no. 11 fiber waveguide for 25 MHz, field 11 띠 (Frequency Required ∞ Table

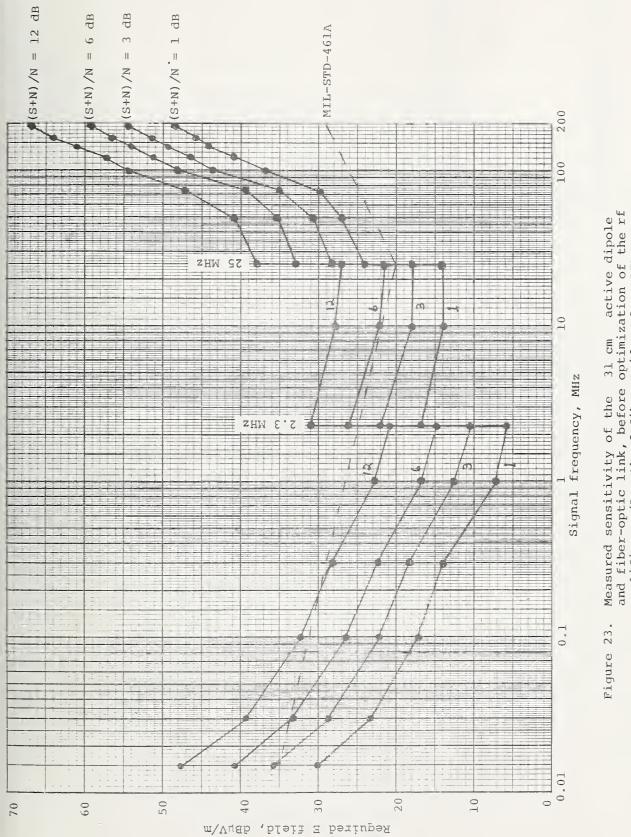
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for no rf Signal Indication Receiver -13 -11.5 -9.5 -6 -3.5 -2.0 1.5 <u>ں</u> S dBuV -12 10 12 14 18 20 222 dB 80.4 71.6 69.2 63.8 64.6 29.9 26.0 24.0 23.7 22.9 25.1 22.6 22.4 22.5 32.4 28.8 25.7 25.4 dB Above Noise 226 186 178 180 E Field, µV/m, . \sim 17.2 15.3 14.0 14.0 41.2 38.5 34.3 34.3 15.0 14.0 12.6 12.4 12.3 90.2 89.1 12.7 12.2 12.2 11.2 р 124 100 5 9 25.4 23.2 22.6 21.9 22.4 dB 78.5 63.8 57.5 56.2 00 00 00 00 00 00 00 9.4 8.5 8.0 7.9 7.8 8.5 7.7 7.8 7.9 Given 10 8 8 9 Required m dB 9.8 10.0 7.9 7.5 31.6 25.1 22.4 22.4 <u>-</u>..... 2.9 2.9 3.3 3.2 3.1 3.1 for 4 ~ ~ ~ ~ ഗ . 0 Current, APD μА 40 50 60 30 40 50 60 3040 50 60 75 0 Ю 30 S 60 30 40 50 60 75 \mathbf{c} 5 4 Bandwidth Receiver NB Band & NB NB WB NB 10 10 10 11 11 . Dipole ED E S S EU E U щ Gap 0.5 0.5 <u>ں</u> ۲ * 0

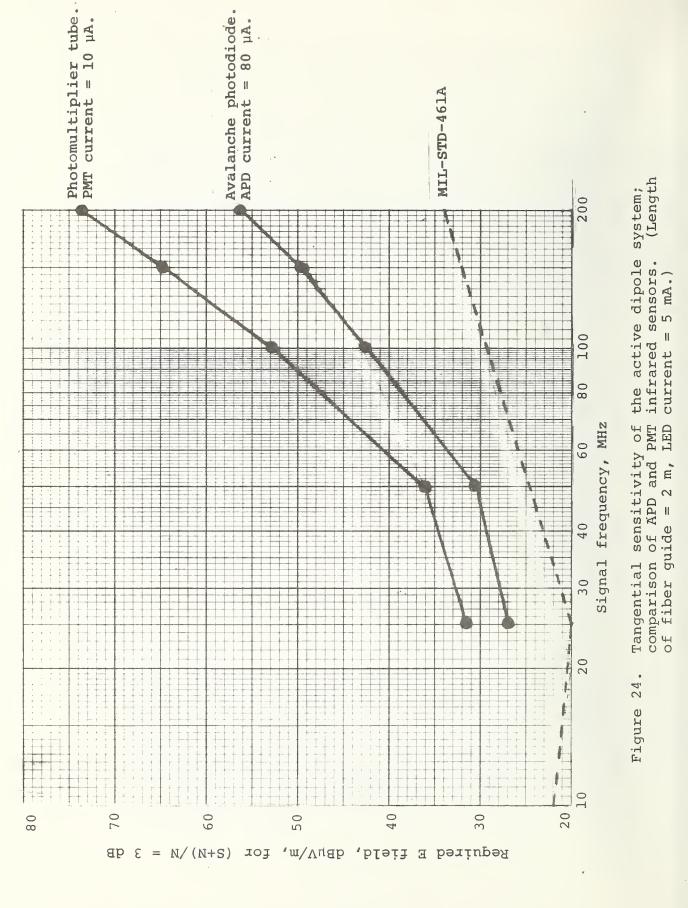
amplifier between the APD and receiver.)

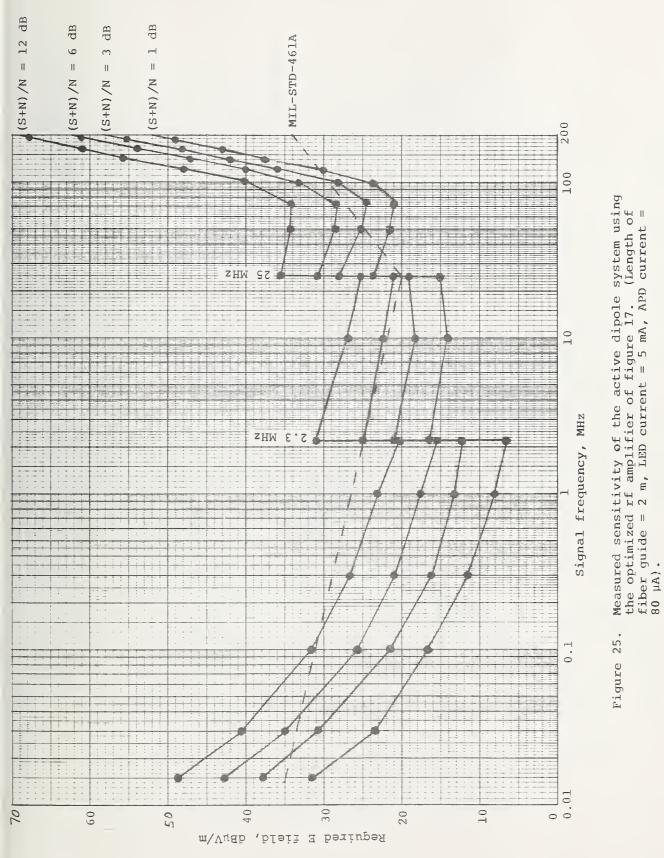
an external wideband rf

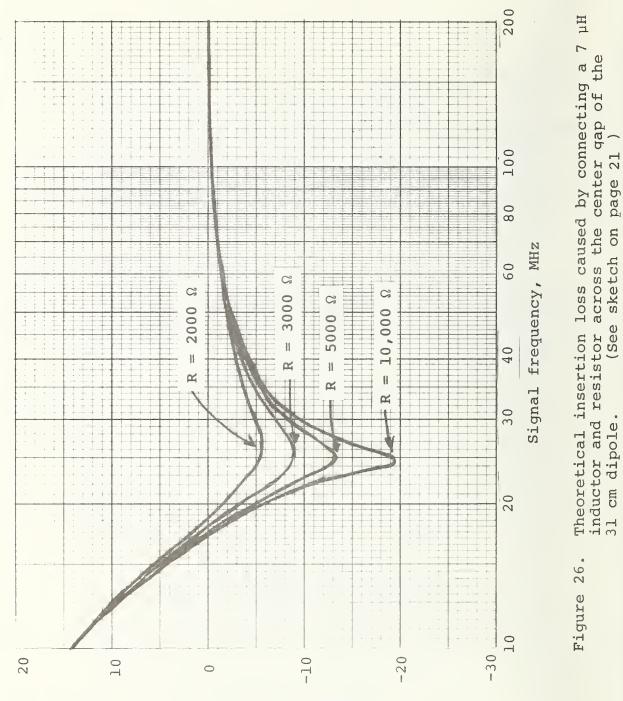
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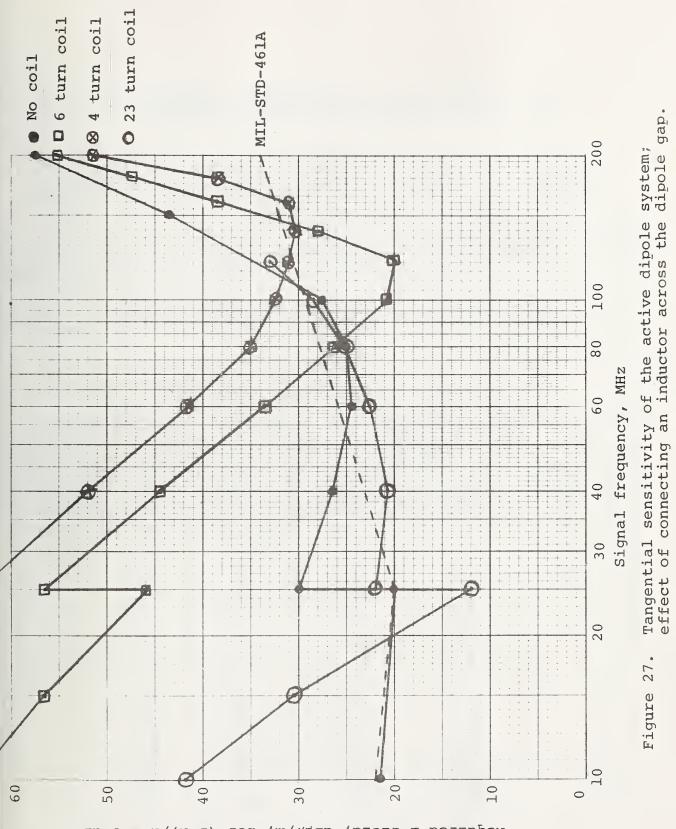
and fiber-optic link, before optimization of a amplifier. (Length of fiber guide = 2 m, LED current = 5 mA, APD current = 80 µA.)







Insertion loss, dB



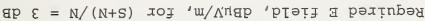


Table 9. Description of the parallel-resonating coils used with the final active antenna.

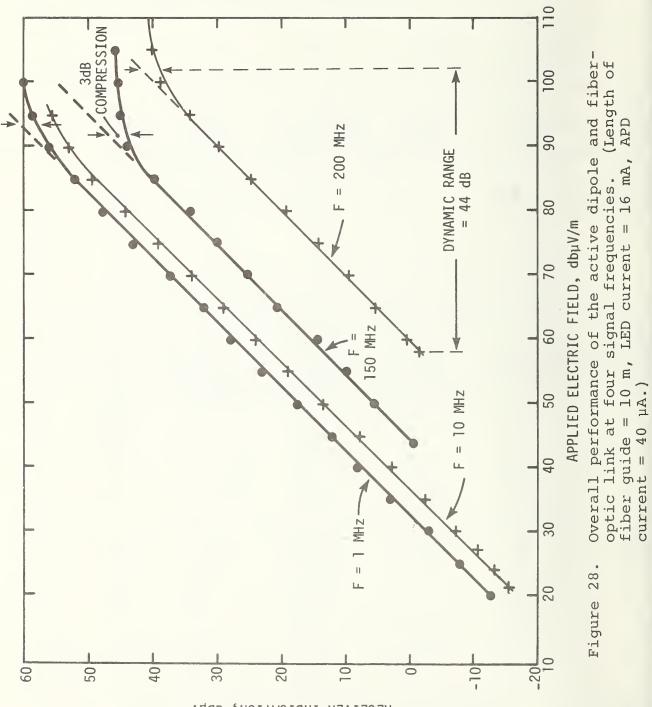
Type of Core	Wire Size	Number of Turns	Series Resistor
Two Q3	#36	23	50 Ω
One Q3	#30	6	10 Ω
One Q3	#30	4	None
	of Core Two Q3 One Q3	of Core Size Two Q3 #36 One Q3 #30	of CoreSizeof TurnsTwo Q3#3623One Q3#306

Table 10. Measured performance of the fiber-optic antenna system.

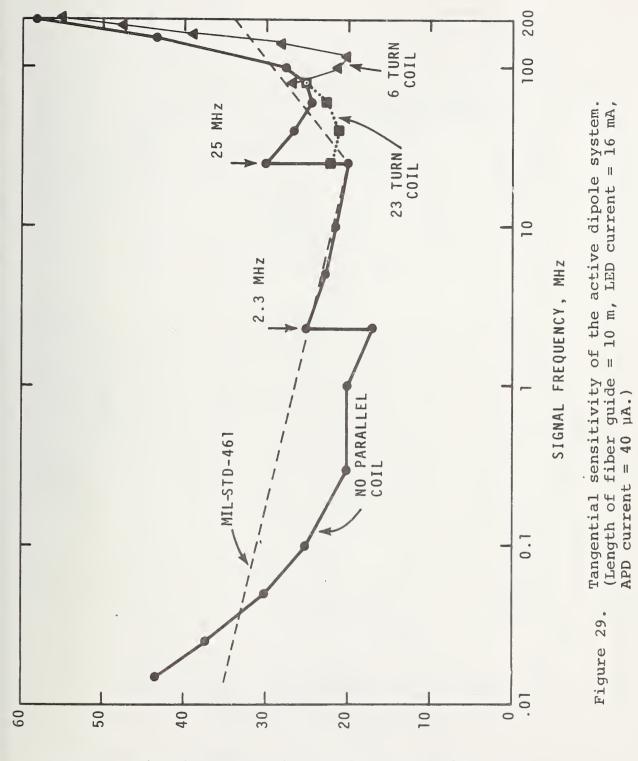
Signal	Receiver	Tangential	Overload	Dynamic	Antenna
Frequency	Band	Sensitivity,	Level,	Range,	Factor,
MHz	Number	dBµV/m	dBµV/m	dB	dB
$\begin{array}{c} 0.015\\ 0.025\\ 0.05\\ 0.1\\ 0.3\\ 1\\ 2.3\\ 2.3\\ 5\\ 10\\ 25\\ 25\\ 40\\ 60\\ 80\\ 100\\ 150\\ 200\\ \end{array}$	1 2 3 5 6 7 8 9 9 10 11 11 12 12 12 13 13 13	$\begin{array}{r} 43.5\\37.5\\30\\25\\20\\20\\17\\25\\23\\21.5\\20\\30\\26.5\\24.5\\25\\27.5\\43.5\\58\end{array}$	110.5 110.5 103 99 92 93.5 87 92 86 91.5 86 85 77.5 66.5 64 73.5 92 102	67 73 74 72 73.5 70 67 63 70 66 55 51 42 39 46 48.5 44	54.5 47 37.5 33.5 30.5 32.5 32.5 32.5 32.5 32.5 30.5 30.5 30.5 30.5 32.5 20 17 27 44.5 60

Table 11.	Measured performance of the fiber-optic antenna
	system with an inductor across the dipole gap.

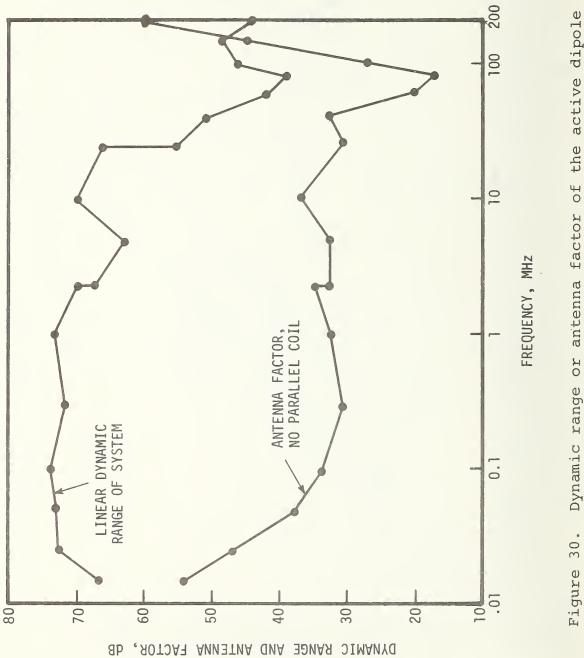
Type of Parallel Inductor	Signal Frequency, MHz	Receiver Band Number	Tangential Sensitivity, dBµV/m	Overload Level, dBµV/m	Dynamic Range, dB	Antenna Factor dB
23 turn toroid, 50 Ω serie resistor	10 15 25 25 40 60 80 100 120	9 10 11 11 12 12 13 13	42 30.5 12 22.5 21 23 25 28.5 33	110 99.5 81 79.5 72 57 66 75.5 78	68 69 57 51 34 41 47 45	55.1 43.4 23.7 23.9 17.7 18.3 18.2 28.4 34.1
6 turn toroid, 10 Ω serie resistor	10 15 25 25 40 60 80 100 120 140 160 180 200	9 10 10 11 12 12 13 13 13 13 13 13 13 13	64 57 46 56.5 44.5 33.5 26 20.5 20 28 38.5 47.5 55.5	123 121 110 109.5 94.3 66.5 62 68.5 66 77 86.5 92.5 100.5	59 64 53 50 33 36 48 46 49 48 45 45	76.5 67.2 55.9 55.8 39.7 20.6 14.2 20.3 19.9 35.6 41.6 51.4 58.2
4 turn toroid	25 40 60 80 100 120 140 160 180 200	11 11 12 12 13 13 13 13 13 13 13	63.5 52 41.5 35 32.5 31 30.5 31 38.5 51.5	116.5 100 74.5 71 78.5 78 83.5 75.5 85.5 95.5	53 48 33 36 46 47 53 44.5 47 44	63.2 47.9 27.3 24.7 33.5 34 36.8 30 40.3 54.2



ΚΕCEIVER ΙΝDICATION, dBµV



KEQUIRED E FIELD, $dB\mu V/m$, FOR (S+N)/N = 3 dB



= 10 m, LED current = system. (Length of fiber guide 16 mA, APD current = 40 µA.)

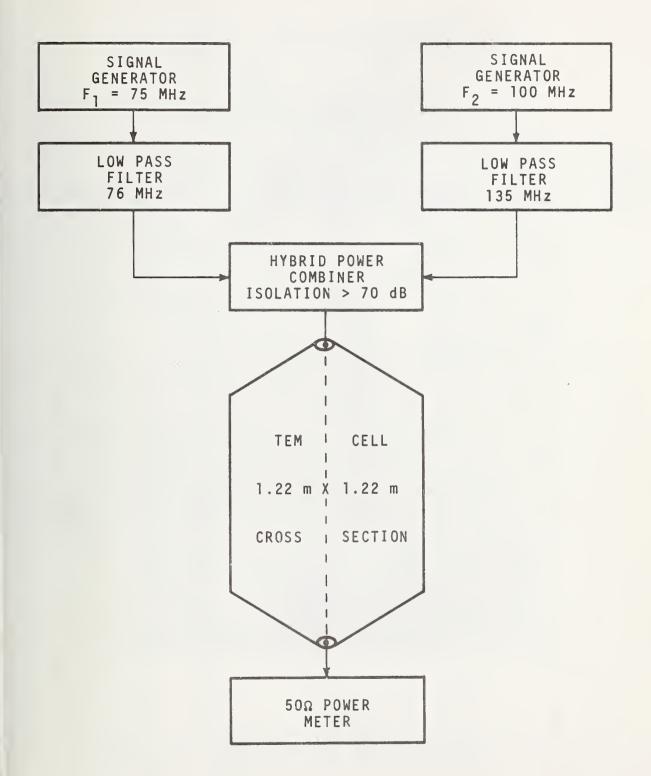


Figure 31. Instrumentation for measuring strong-signal desensitization of the active dipole system.

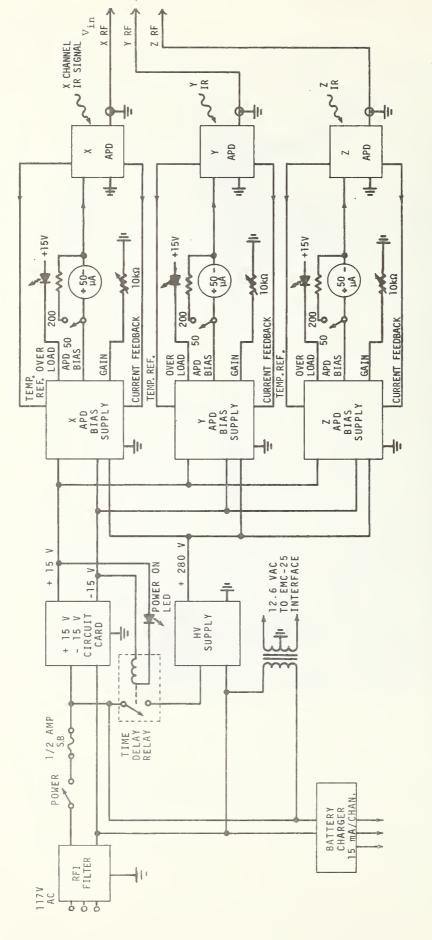
Table 12. Desensitization of the active dipole system; measurements of a "desired" signal at 75 MHz in the presence of an "interfering" signal at 100 MHz.

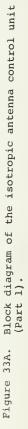
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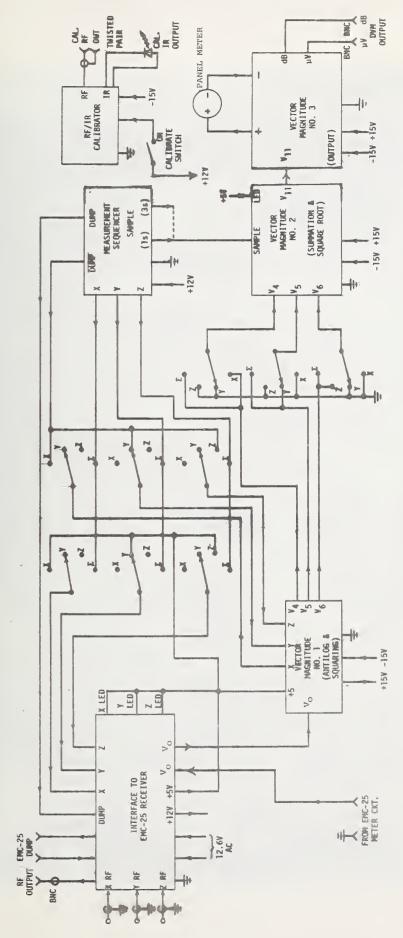
(Interfering Signal) E field at 100 MHz,. dBµV/m	(Desired Signal) E field at 75 MHz, dBµV/m	Receiver Indication, dBµV	Antenna Factor, dB	(Interfering Signal) E field at 100 MHz, dBµV/m	(Desired Signal) E field at 75 MHz, dBµV/m	Receiver Indication, dBµV	Antenna Factor, dB
0	23.2 27 30 35 40 45 50 55 60 65 70 75 80 85 90	6.8 9.7 12.5 18.2 23 28 32.5 38.2 41 42.2 43.5 45.5 47.2 47.8 46	16.4 17.3 17.5 16.8 17 17.5 16.8 19 22.8 26.5 29.5 32.8 37.2 44	70	25.5 27 30 35 40 45 50 55 60 65 70 75 80 85 90	$ \begin{array}{c} 2 \\ 3 \\ 5 \cdot 8 \\ 10 \cdot 8 \\ 16 \\ 21 \\ 26 \cdot 2 \\ 30 \\ 34 \cdot 8 \\ 40 \\ 42 \cdot 5 \\ 44 \cdot 5 \\ 46 \cdot 2 \\ 47 \cdot 2 \\ 44 \cdot 7 \\ \end{array} $	23.5 24 24.2 24.2 24 23.8 25 25.2 25 27.5 30.5 33.8 37.8 45.3
50	24.1 27 30 35 40 45 50 55 60 65 70 75 80 85 90	7 9 11.8 17.3 22.2 28 31.8 37.2 40.5 42 43.2 45 46.5 47.2 44.5	17.1 18 18.2 17.8 17.8 17 18.2 17.8 19.5 23 26.8 30 34.5 37.8 45.5	80	27.1 30 35 40 45 50 55 60 65 70 75 80 85 90 95	-3 -1 3.8 8.3 13.2 18.7 22.5 29 33.5 37.5 41.5 44.2 46.2 45.5 43.7	30.1 31.2 31.7 31.8 31.3 32.5 31 31.5 32.5 33.5 35.8 38.2 44.5 51.3
60	24.7 27 30 35 40 45 50 55 60 65 70 75 80 85 90	$\begin{array}{c} 6.8\\ 8.7\\ 11.3\\ 17.2\\ 22\\ 27.5\\ 31.5\\ 36.7\\ 40\\ 41.8\\ 43\\ 44.8\\ 46.3\\ 47.2\\ 45.5 \end{array}$	17.9 18.3 18.7 17.8 18 17.5 18.5 18.3 20 23.2 27 30.2 33.7 37.8 44.5	90	36.1 40 45 50 55 60 65 70 75 80 85 90 95 100 105	-4.8 -1.5 3.5 8 12.8 18 23.5 29 34 39.5 42 45.5 45.5 45.7 45.8	40.9 41.5 41.5 42 42.2 42.2 41.5 41 41 40.5 43 45 49.5 54.3 59.2



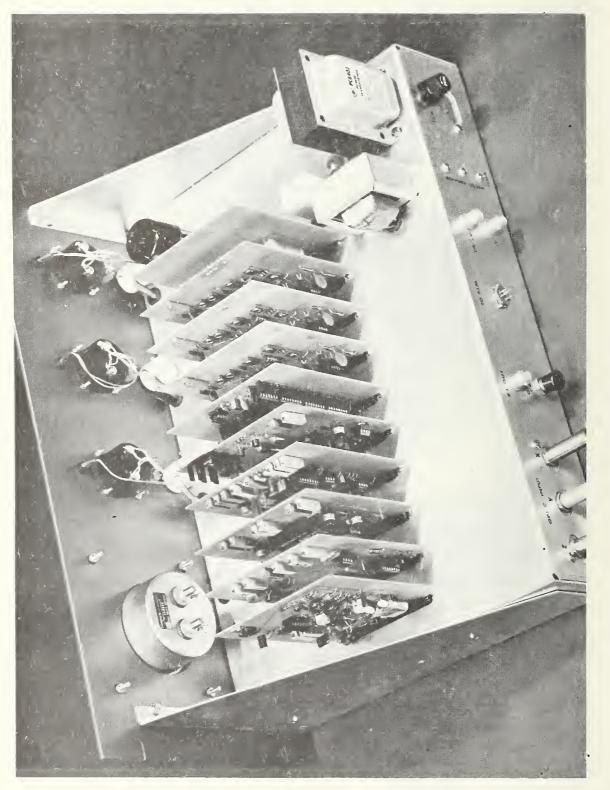
Figure 32. Photograph of the isotropic antenna.











Photograph of the antenna control unit chassis. Figure 34.



Figure 35. Photograph of the complete fiber-optic antenna measurement system including the crossed dipoles, fiber guides, control unit and conventional receiver.

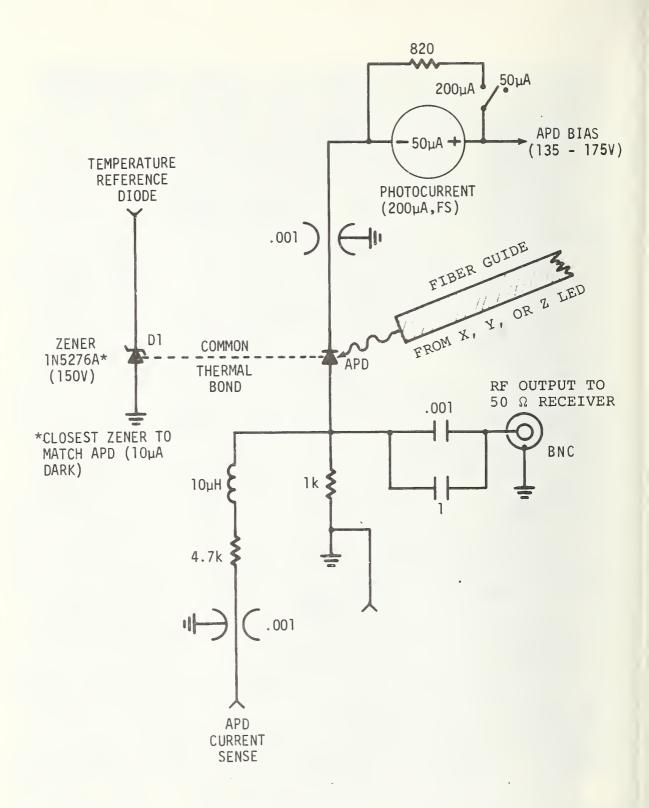
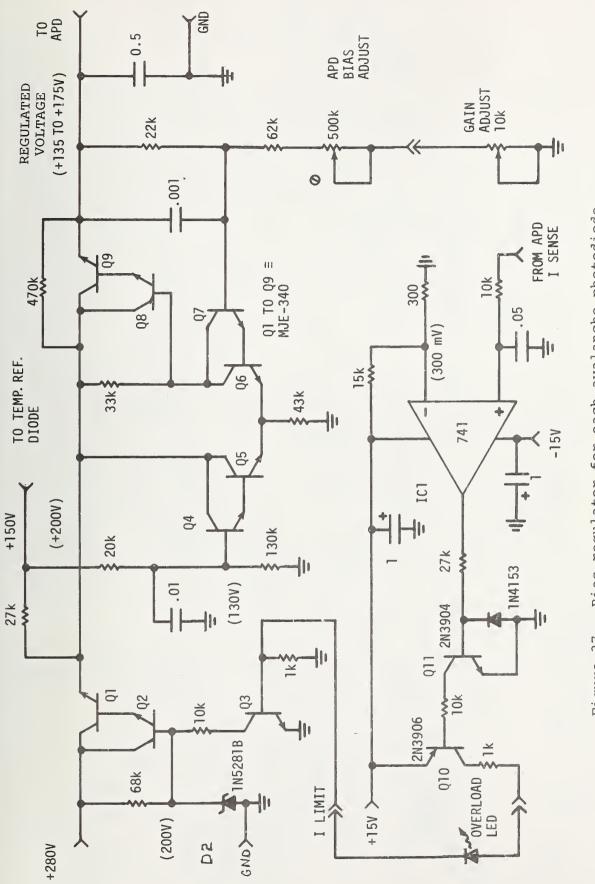
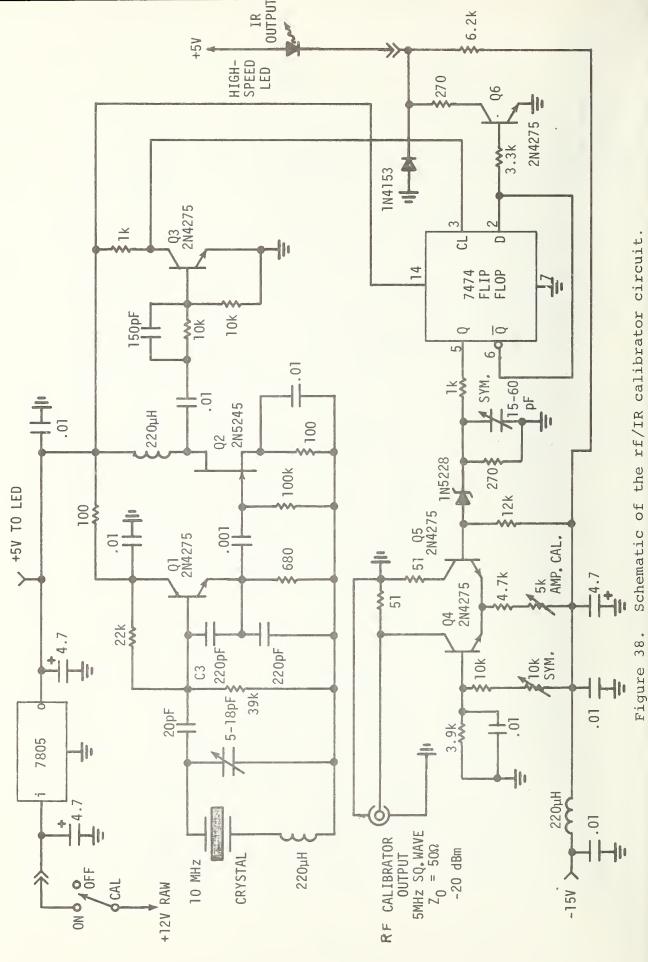
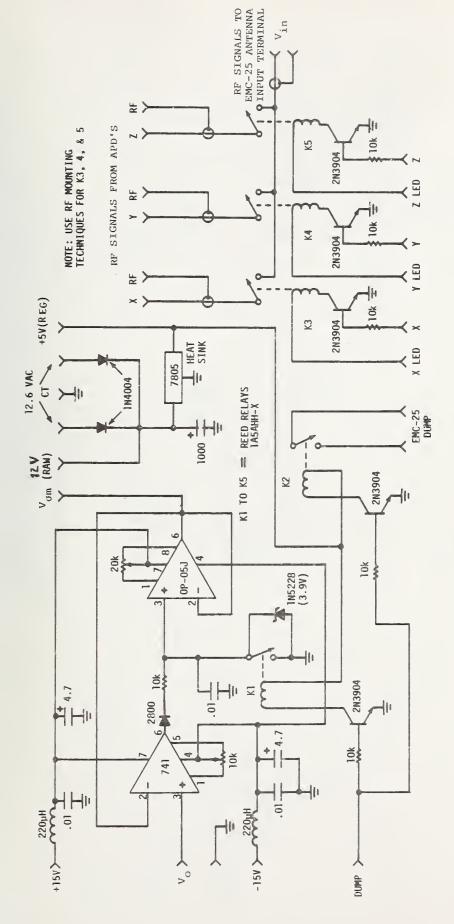


Figure 36. Schematic of each avalanche photodiode circuitry.

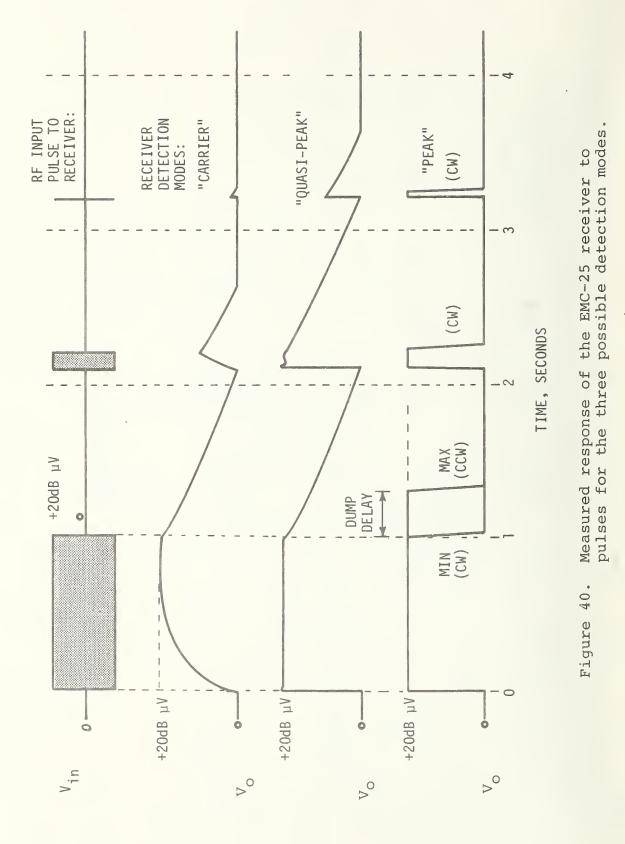


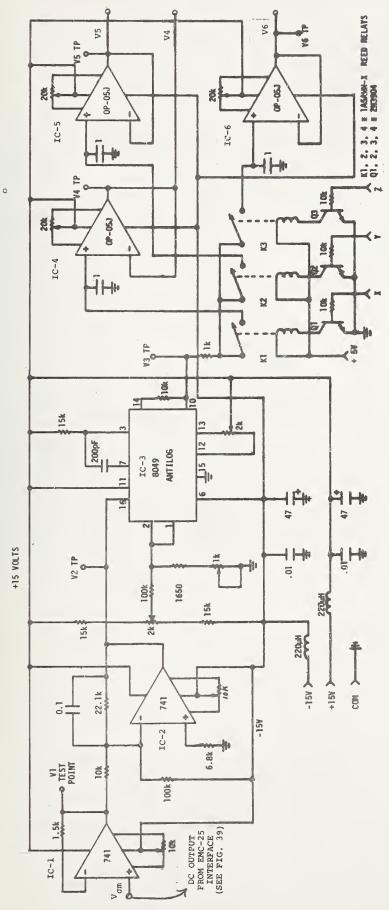
Bias regulator for each avalanche photodiode. Figure 37.





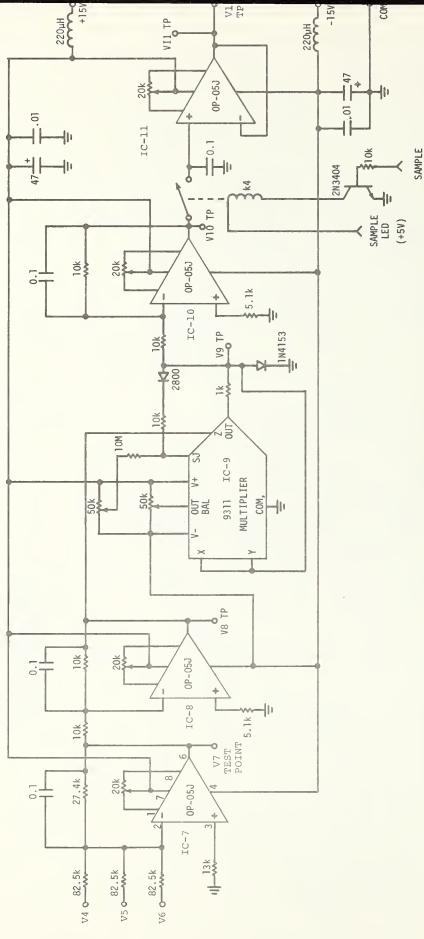




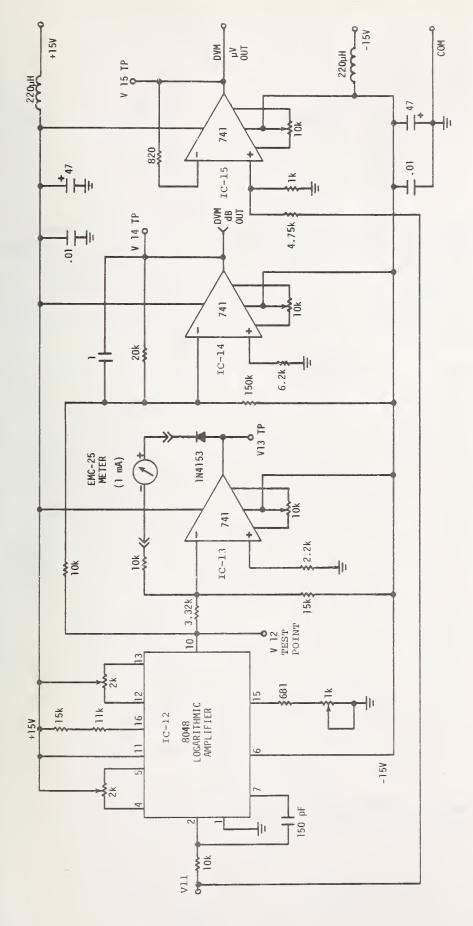




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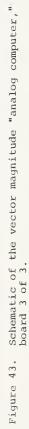


Table 13.	"Analog	computer"	voltages	for	various	antenna	input	voltages.
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	Channel	Channel X, Y or Z antenna voltage					
					l7.32 μV (i.e., 10 μV on each channel)		
V _o , V _{om} , Vl	0.15 V	0.60 V	1.05 V	1.50 V	1.50 V		
v ₂	3.00 V	2.00 V	1.00 V	0.00 V	0.00 V		
v ₃ ,v ₄ ,v ₅ ,v ₆	lo µV	l mV	100 mV	10.0 V	10.0 V		
v ₇	-3.33 µV	-333 µV	-33.3 mV	-3.33 V	-10 · V		
V ₈	3.33 µV	333 µV	33.3 mV	3.33 V	10 V		
v ₉	-5.77 mV	-57.7 mV	-577 mV	-5.77 V	-10 V		
v ₁₀ ,v ₁₁	5.77 mV	57.7 mV	577 mV	5.77 V	10 V		
V ₁₂	3.0 V	2.0 V	1.0 V	0.0 V	-239 mV		
V ₁₃	1.0 V	4.0 V	7.0 V	10.0 V	10.7 V		
I (meter)	0.1 mA	0.4 mA	0.7 mA	1.0 mA	1.07 mA		
V ₁₄ (dB out)	-4.0 V	-2.0 V	0.0 V	2.0 V	2.48 V		
$V_{15}(\mu V \text{ out})$	l mV	10 mV	100 mV	1.0 V	1.73 V		
Meter Reading	0.01 µV*	0.l µV	1.0 µV	10 µV	off scale		

*Note: Actual analog computer voltages and outputs are invalid for antenna input voltage less than 0.1 µV.

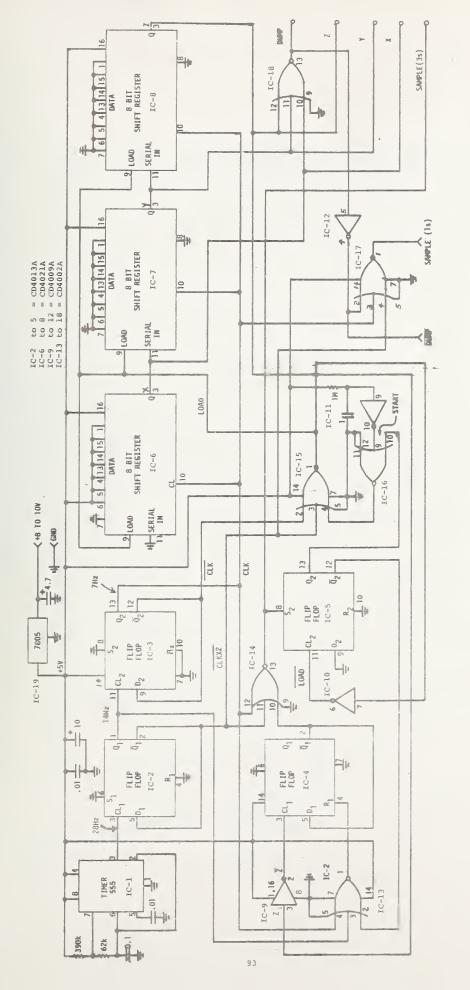
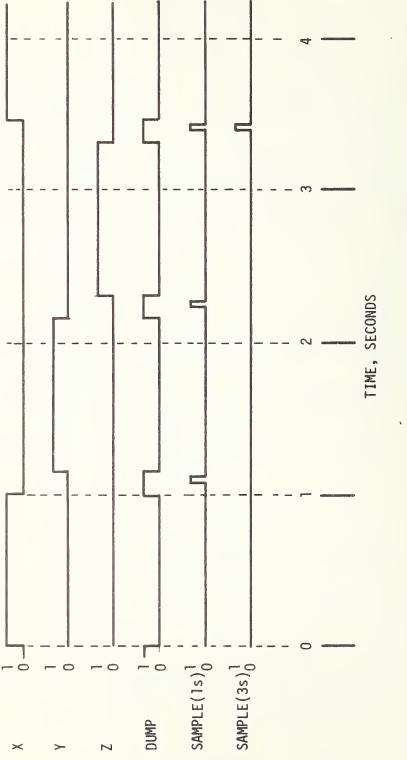


Figure 44. Schematic of the measurement sequencer circuitry.





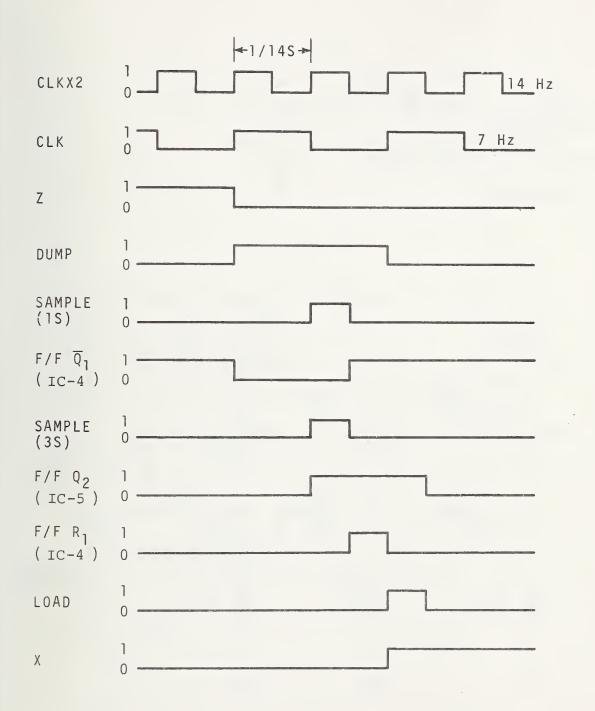


Figure 46. Timing diagrams of the measurement sequencer interval signals.

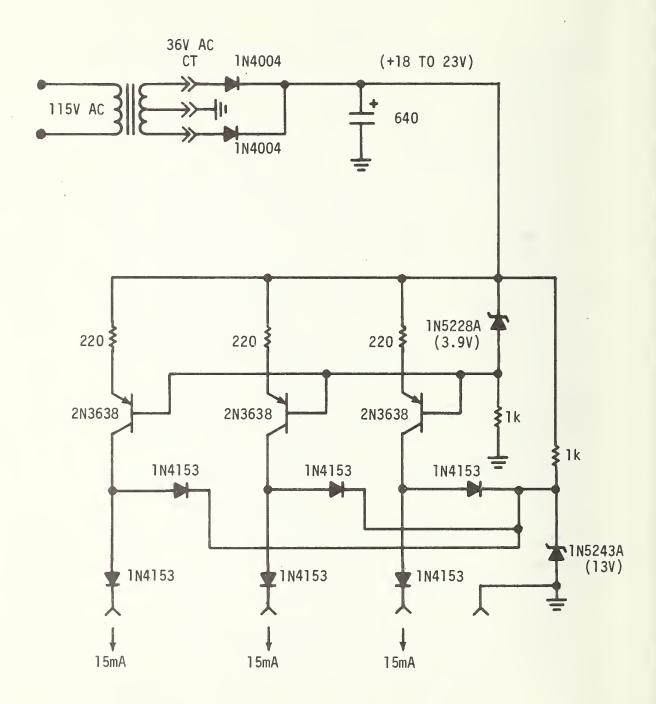
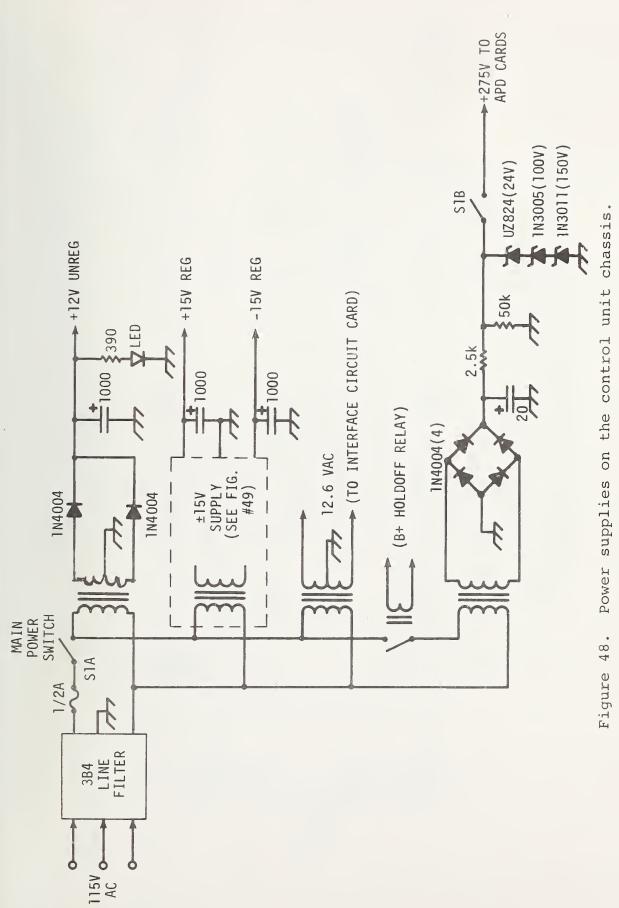
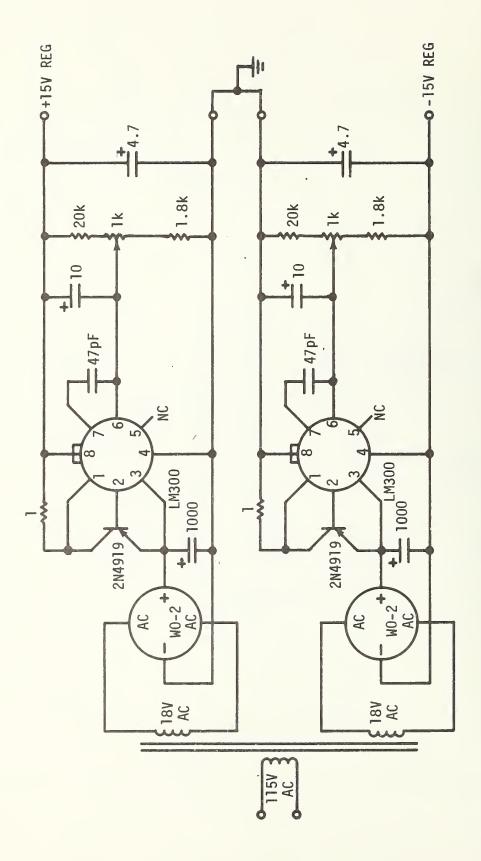


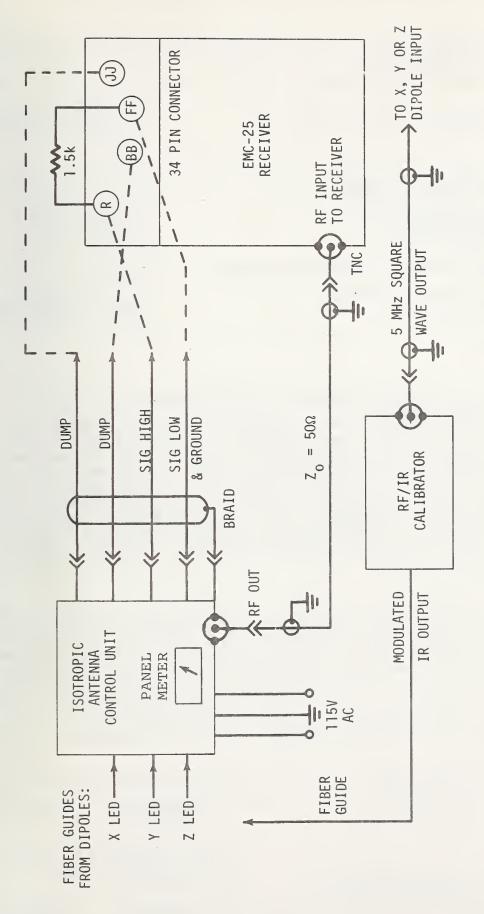
Figure 47. Schematic of the charger for the NiCd batteries.

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Schematic of the ± 15 volt regulated power supply. Figure 49.



Interconnecting cables between the control unit, EMC-25 receiver and the rf/IR calibrator. Figure 50.

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bibliography or literature su A broadband, act frequency range 15 kl	less factual summary of most significant irvey, mention it here.) tive, isotropic receiving an Hz to 150 MHz. It was design ak. near-zone electric field	ntenna was devel gned for use wit	oped at NBS for the h a conventional re-

rrequency range 15 kHz to 150 MHz. It was designed for use with a conventional receiver to measure weak, near-zone electric fields of unknown polarization, such as leakage emanations from electronic equipment placed within a shielded enclosure. The antenna system consists of three mutually-orthogonal active dipoles, each 31 cm long by 3.5 cm diameter. The entire frequency range of each of the three field components is amplified and used to modulate a high-speed light emitting diode (LED) located inside the dipole. The modulated infrared (IR) signals are guided through glass fibers 10 meters long which connect the "isolated" dipoles to avalanche photodiodes at the far end of the fiber guides. These photodetectors recover the rf modulation from the IR carrier for input to the receiver.

The fiber-optic antenna system described in this paper has high sensitivity (down to 10 μ V/m) and fast response time (rf modulations up to 150 MHz). The readout indication at each receiver frequency is proportional to the Hermitian magnitude of E, which is the root-sum-square value of three orthogonal E field components at the measurement point. The linear dynamic range of the antenna system depends on the receiver bandwidth and signal frequency. It is 70 to 75 dB at frequencies between 0.02 and 2 MHz (for 0.5 kHz receiver bandwidth), 60 to 70 dB between 2 and 25 MHz (for 5 kHz receiver bandwidth) and 40 to 55 dB between 25 and 200 MHz (for 50 kHz bandwidth).

17. KEY WORDS (six to twelve entries; alphabetical order; capitalize only the first letter of the first key word unless a proper name; separated by semicolons)

Electromagnetic compatibility; fiber optics; field strength measurement; isolated EMC antenna; sensitive isotropic probe.

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